PIC18(L)F2X/4XK40 Memory Programming Specification

1.0 OVERVIEW

This programming specification describes an SPI-based programming method for the PIC18(L)F2X/4XK40 family of microcontrollers. **Section 3.0 "Programming Algorithms"** describes the programming commands, programming algorithms and electrical specifications which are used in that particular programming method. **Appendix B** contains individual part numbers, device identification and checksum values, pinout and packaging information, and Configuration Words.

Note 1: This is a SPI-compatible programming method with 8-bit commands.

2: The low-voltage entry code is now 32 clocks and MSb first, unlike previous PIC18 devices which had 33 clocks and LSb first.

1.1 Programming Data Flow

Nonvolatile Memory (NVM) programming data can be supplied by either the high-voltage In-Circuit Serial Programming™ (ICSP™) interface or the low-voltage In-Circuit Serial Programming (ICSP) interface. Data can be programmed into the Program Flash Memory (PFM), Data EEPROM Memory, dedicated "User ID" locations and the Configuration Words.

1.2 Write and/or Erase Selection

Erasing or writing is selected according to the command used to begin operation (see Table 3-1). The terminologies used in this document, related to erasing/writing to the program memory, are defined in Table 1-1 and are detailed below.

TABLE 1-1: PROGRAMMING TERMS

Term	Definition
Programmed Cell	A memory cell at logic '0'
Erased Cell	A memory cell at logic '1'
Erase	Change memory cell from a '0' to a '1'
Write	Change memory cell from a '1' to a '0'
Program	Generic erase and/or write

1.2.1 ERASING MEMORY

Memory is erased by row or in bulk, where 'bulk' includes many subsets of the total memory space. The duration of the erase is determined by the size of program memory. All Bulk ICSP Erase commands have minimum VDD requirements, which are higher than the Row Erase and write requirements.

1.2.2 WRITING MEMORY

Memory is written one row at a time. Multiple load data for NVM commands is used to fill the row data latches. The duration of the write can be determined either internally or externally.

1.2.3 MULTI-WORD PROGRAMMING INTERFACE

Program Flash Memory (PFM) panels include up to a 64-word (one row) programming interface. Refer to Table 3-3 for row size of erase and write operations for the PIC18(L)F2X/4XK40 family. The row to be programmed must first be erased, either with a Bulk Erase or a Row Erase.

1.3 Hardware Requirements

1.3.1 HIGH-VOLTAGE ICSP PROGRAMMING

In High-Voltage ICSP mode, the device requires two programmable power supplies: one for VDD and one for the MCLR/VPP pin.

1.3.2 LOW-VOLTAGE ICSP PROGRAMMING

In Low-Voltage ICSP mode, the device can be programmed using a single VDD source in the operating range. The MCLR/VPP pin does not have to be brought to programming voltage, but can instead be left at the normal operating voltage.

1.3.2.1 Single-Supply ICSP Programming

The device's LVP Configuration bit enables single-supply (low-voltage) ICSP programming. The LVP bit defaults to a '1' (enabled). The LVP bit may only be programmed to '0' by entering the High-Voltage ICSP mode, where the MCLR/VPP pin is raised to VIHH. Once the LVP bit is programmed to a '0', only the High-Voltage ICSP mode is available and only the High-Voltage ICSP mode can be used to program the device.

Note 1: The High-Voltage ICSP mode is always available, regardless of the state of the LVP bit, by applying VIHH to the MCLR/VPP pin.

2: While in Low-Voltage ICSP mode, MCLR is always enabled, regardless of the MCLRE bit. Also, the port pin can no longer be used as a general purpose input.

1.4 Pin Utilization

Five pins are needed for ICSP programming. The pins are listed in Table 1-2. For pin locations and packaging information, please refer to Table B-3.

TABLE 1-2: PIN DESCRIPTIONS DURING PROGRAMMING

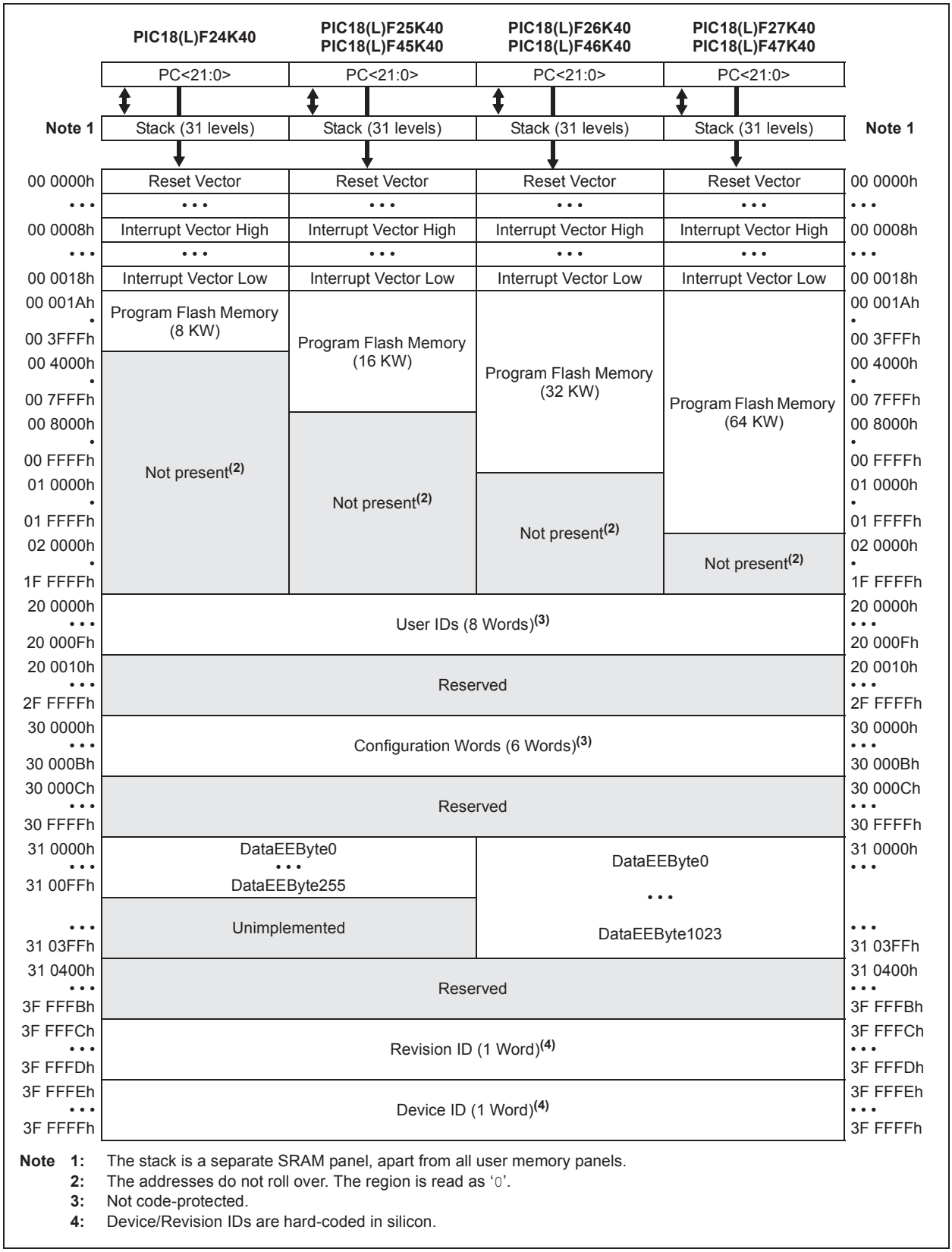
Pin Name	During Programming		
	Function	Pin Type	Pin Description
ICSPCLK	ICSPCLK	I	Clock Input – Schmitt Trigger Input
ICSPDAT	ICSPDAT	I/O	Data Input/Output – Schmitt Trigger Input
MCLR/VPP	Program/Verify mode	I(1)	Program Mode Select
VDD	VDD	P	Power Supply
VSS	VSS	P	Ground

Legend: I = Input, O = Output, P = Power

Note 1: The programming high voltage is internally generated. To activate the Program/Verify mode, high voltage needs to be applied to the MCLR input. Since the MCLR is used for a level source, MCLR does not draw any significant current.

2.0 MEMORY MAP

TABLE 2-1: PROGRAM AND DATA EEPROM MEMORY MAP



Note 1: The stack is a separate SRAM panel, apart from all user memory panels.
2: The addresses do not roll over. The region is read as '0'.
3: Not code-protected.
4: Device/Revision IDs are hard-coded in silicon.

TABLE 2-2: MEMORY MAP AND CODE PROTECTION CONTROL

Reg.	Address (from/to)	Device			
		PIC18(L)F24K40	PIC18(L)F25K40 PIC18(L)F45K40	PIC18(L)F26K40 PIC18(L)F46K40	PIC18(L)F27K40 PIC18(L)F47K40
PFM	00 0000h 00 07FFh	Boot Block 1 KW CP, WRTB, EBTRB	Boot Block 1 KW CP, WRTB, EBTRB	Boot Block 1 KW CP WRTB, EBTRB	Boot Block 1 KW CP WRTB, EBTRB
	00 0800h 00 1FFFh	Block 0 3 KW CP, WRT0, EBTR0	Block 0 3 KW CP, WRT0, EBTR0	Block 0 7 KW CP, WRT0, EBTR0	Block 0 7 KW CP, WRT0, EBTR0
	00 2000h 00 3FFFh	Block 1 4 KW CP, WRT1, EBTR1	Block 1 4 KW CP, WRT1, EBTR1		
	00 4000h 00 5FFFh	Not present	Block 2 4 KW CP, WRT2, EBTR2	Block 1 8 KW CP, WRT1, EBTR1	Block 1 8 KW CP, WRT1, EBTR1
	00 6000h 00 7FFFh		Block 3 4 KW CP, WRT3, EBTR3		
	00 8000h 00 BFFFh		Not present	Block 2 8 KW CP, WRT2, EBTR2	Block 2 8 KW CP, WRT2, EBTR2
	00 C000h 00 FFFFh			Block 3 8 KW CP, WRT3, EBTR3	Block 3 8 KW CP, WRT3, EBTR3
	01 0000h 01 3FFFh			Not present	Block 4 8 KW CP, WRT4, EBTR4
	01 4000h 01 7FFFh				Block 5 8 KW CP, WRT5, EBTR5
	01 8000h 01 BFFFh				Block 6 8 KW CP, WRT6, EBTR6
	01 C000h 01 FFFFh				Block 7 8 KW CP, WRT7, EBTR7
CONFIG	30 0000h 30 000Bh	6 Words WRTC			
Data EEPROM	31 0000h 31 00FFh	256 Words CPD, WRTD		1 KW CPD, WRTD	
	31 0100h 31 03FFh	Unimplemented			

2.1 User ID Location

A user may store identification information (User ID) in eight designated locations. The User ID locations are mapped to 20 0000h-20 000Fh. Each location is 16 bits in length. It is recommended that the Most Significant nibble of each ID be Fh. In doing so, if the user code inadvertently tries to execute from the ID space, the ID data will execute as a NOP. Code protection has no effect on these memory locations. Each location may be read with code protection enabled or disabled.

2.2 Device/Revision ID

The 16-bit Device ID Word is located at 3F FFFEh and the 16-bit Revision ID is located at 3F FFFCh. These locations are read-only and cannot be erased or modified.

REGISTER 2-1: DEVICEID: DEVICE ID REGISTER

R	R	R	R	R	R	R	R
DEV15	DEV14	DEV13	DEV12	DEV11	DEV10	DEV9	DEV8
bit 15							bit 8

R	R	R	R	R	R	R	R
DEV7	DEV6	DEV5	DEV4	DEV3	DEV2	DEV1	DEV0
bit 7							bit 0

Legend:			
R = Readable bit	‘1’ = Bit is set	0’ = Bit is cleared	x = Bit is unknown

bit 15-0 **DEV<15:0>:** Device ID bits

REGISTER 2-2: REVISIONID: REVISION ID REGISTER

R	R	R	R	R	R	R	R
1	0	1	0	MJRREV<5:2>			
bit 15							bit 8

R	R	R	R	R	R	R	R
MJRREV<1:0>		MNRREV<5:0>					
bit 7							bit 0

Legend:			
R = Readable bit	‘1’ = Bit is set	0’ = Bit is cleared	x = Bit is unknown

bit 15-12 **Read as ‘1010’**
These bits are fixed with value, ‘1010’, for all devices in this programming specification.

bit 11-6 **MJRREV<5:0>:** Major Revision ID bits
These bits are used to identify a major revision. A major revision is indicated by an all layer revision (A0, B0, C0, etc...).
Revision A = 6’b00_0000

bit 5-0 **MNRREV<5:0>:** Minor Revision ID bits
These bits are used to identify a minor revision.
Revision A0 = 6’b00_0000

2.3 Configuration Words

The devices have six Configuration Words starting at address, 30 0000h. The individual bits within these Configuration Words are critical to the correct operation of the system. Configuration bits enable or disable specific features, placing these controls outside the normal software process, and they establish configured values prior to the execution of any software.

In terms of programming, these important Configuration bits should be considered:

1. LVP: Low-Voltage Programming Enable bit

1 = ON – Low-Voltage Programming is enabled. $\overline{\text{MCLR}}$/VPP pin function is $\overline{\text{MCLR}}$. MCLRE Configuration bit is ignored.

0 = OFF – High Voltage on $\overline{\text{MCLR}}$/VPP must be used for programming.

It is important to note that the LVP bit cannot be written (to '0') while operating from the LVP programming interface. The purpose of this rule is to prevent the user from dropping out of LVP mode while programming from LVP mode, or accidentally eliminating LVP mode from the configuration state. For more information, see **Section 3.1.2 "Low-Voltage Programming (LVP) Mode"**.

2. MCLRE: Master Clear ($\overline{\text{MCLR}}$) Enable bit

- If LVP = 1

  RE3 pin function is $\overline{\text{MCLR}}$

- If LVP = 0

  1 = $\overline{\text{MCLR}}$ pin is $\overline{\text{MCLR}}$
  0 = $\overline{\text{MCLR}}$ pin function is a port defined function

3. $\overline{\text{CPD}}$: Data NVM (EEPROM) Memory Code Protection bit

1 = OFF – Data NVM code protection is disabled
0 = ON – Data NVM code protection is enabled

4. $\overline{\text{CP}}$: User NVM Program Memory Code Protection bit

1 = OFF – User NVM code protection is disabled
0 = ON – User NVM code protection is enabled

For more information on code protection, see **Section 3.3 "Code Protection"**.

3.0 PROGRAMMING ALGORITHMS

3.1 Program/Verify Mode

In Program/Verify mode, the program memory and the configuration memory can be accessed and programmed in serial fashion. ICSPDAT and ICSPCLK are used for the data and the clock, respectively. All commands and data words are transmitted MSb first. Data changes on the rising edge of the ICSPCLK and is latched on the falling edge. In Program/Verify mode, both the ICSPDAT and ICSPCLK are Schmitt Trigger inputs. The sequence that enters the device into Program/Verify mode places all other logic into the Reset state. Upon entering Program/Verify mode, all I/Os are automatically configured as high-impedance inputs and the address is cleared.

3.1.1 HIGH-VOLTAGE PROGRAM/VERIFY MODE ENTRY AND EXIT

There are two different modes of entering Program/Verify mode via high voltage:

- VPP – First Entry mode
- VDD – First Entry mode

3.1.1.1 VPP – First Entry Mode

To enter Program/Verify mode via the VPP-First mode, the following sequence must be followed:

1. Hold ICSPCLK and ICSPDAT low. All other pins should be unpowered.
2. Raise the voltage on $\overline{\text{MCLR}}$ from 0V to VIHH.
3. Raise the voltage on VDD from 0V to the desired operating voltage.

The VPP-First entry prevents the device from executing code prior to entering Program/Verify mode. For example, when the Configuration Word has already been programmed to have $\overline{\text{MCLR}}$ disabled (MCLRE = 0), the Power-up Timer disabled ($\overline{\text{PWRTE}}$ = 0) and the internal oscillator selected, the device will execute code immediately. Since this may prevent entry, VPP-First Entry mode is strongly recommended as it prevents user code from changing EEPROM contents or driving pins to affect Test mode entry. See the timing diagram in Figure 3-1.

3.1.1.2 VDD – First Entry Mode

To enter Program/Verify mode via the VDD-First mode, the following sequence must be followed:

1. Hold ICSPCLK and ICSPDAT low.
2. Raise the voltage on VDD from 0V to the desired operating voltage.
3. Raise the voltage on $\overline{\text{MCLR}}$ from VDD or below to VIHH.

The VDD-First mode is useful for programming the device when VDD is already applied, for it is not necessary to disconnect VDD to enter Program/Verify mode. See the timing diagram in Figure 3-2.

3.1.1.3 Program/Verify Mode Exit

To exit Program/Verify mode, lower $\overline{\text{MCLR}}$ from VIHH or lower (VIL). VPP-First Entry mode should use VPP-Last Exit mode (see Figure 3-1). VDD-First Entry mode should use VDD-Last Exit mode (see Figure 3-2).

FIGURE 3-1: PROGRAMMING ENTRY AND EXIT MODES – VPP-First AND Last

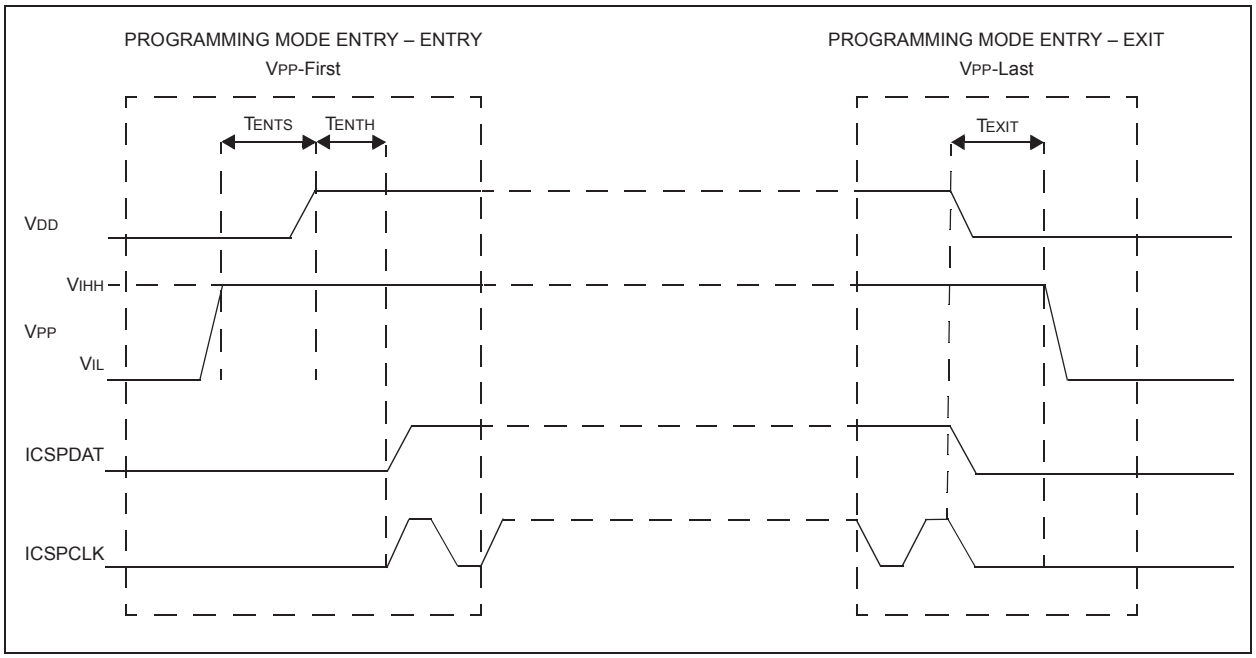
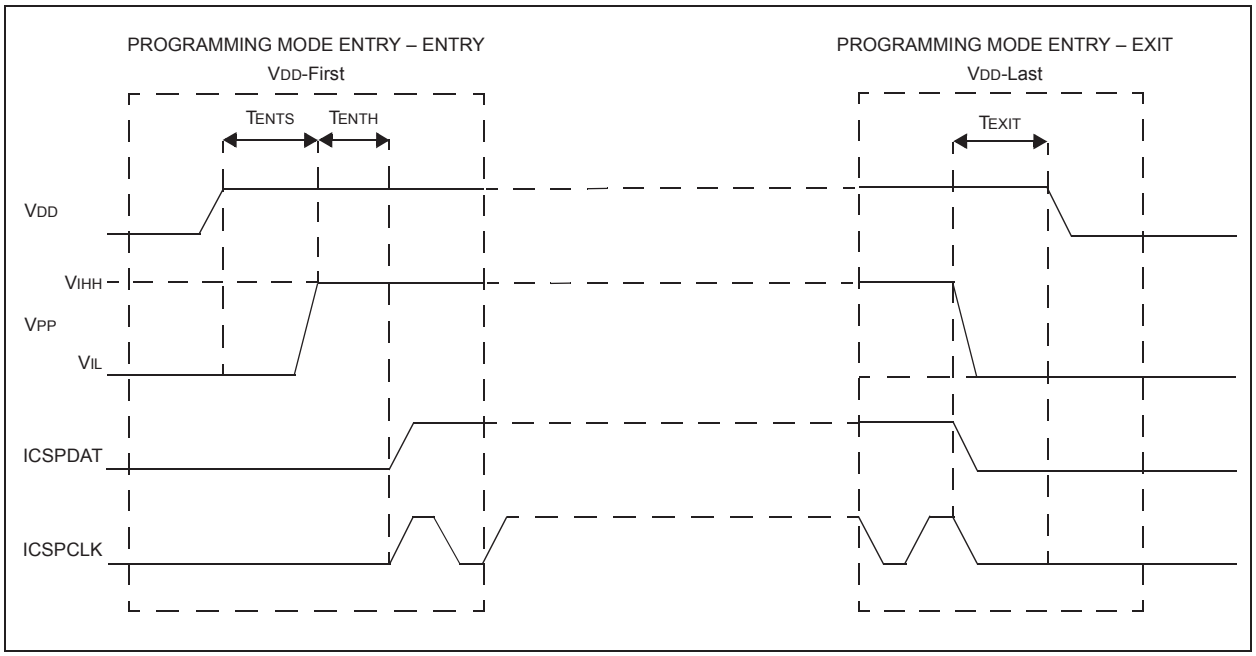


FIGURE 3-2: PROGRAMMING ENTRY AND EXIT MODES – VDD-First AND Last



3.1.2 LOW-VOLTAGE PROGRAMMING (LVP) MODE

The Low-Voltage Programming mode allows the devices to be programmed using VDD only, without high voltage. When the LVP bit of the Configuration Word 3 register is set to '1', the Low-Voltage ICSP Programming entry is enabled. To disable the Low-Voltage ICSP mode, the LVP bit must be programmed to '0'. This can only be done while in the High-Voltage Entry mode.

Entry into the Low-Voltage ICSP Program/Verify mode requires the following steps:

1. $\overline{\text{MCLR}}$ is brought to VIL.
2. A **32-bit key sequence** is presented on ICSPDAT. The LSb of the pattern is a "don't care x". The Program/Verify mode entry pattern detect hardware verifies only the first 31 bits of the sequence and the last clock is required before the pattern detect goes active.

The key sequence is a specific 32-bit pattern, '32'h4d434850' (more easily remembered as MCHP in ASCII). The device will enter Program/Verify mode only if the sequence is valid. The Most Significant bit of the most significant nibble must be shifted in first. Once the key sequence is complete, $\overline{\text{MCLR}}$ must be held at VIL for as long as Program/Verify mode is to be maintained. For Low-Voltage Programming timing, see Figure 3-3 and Figure 3-4.

FIGURE 3-3: LVP ENTRY (POWERING UP)

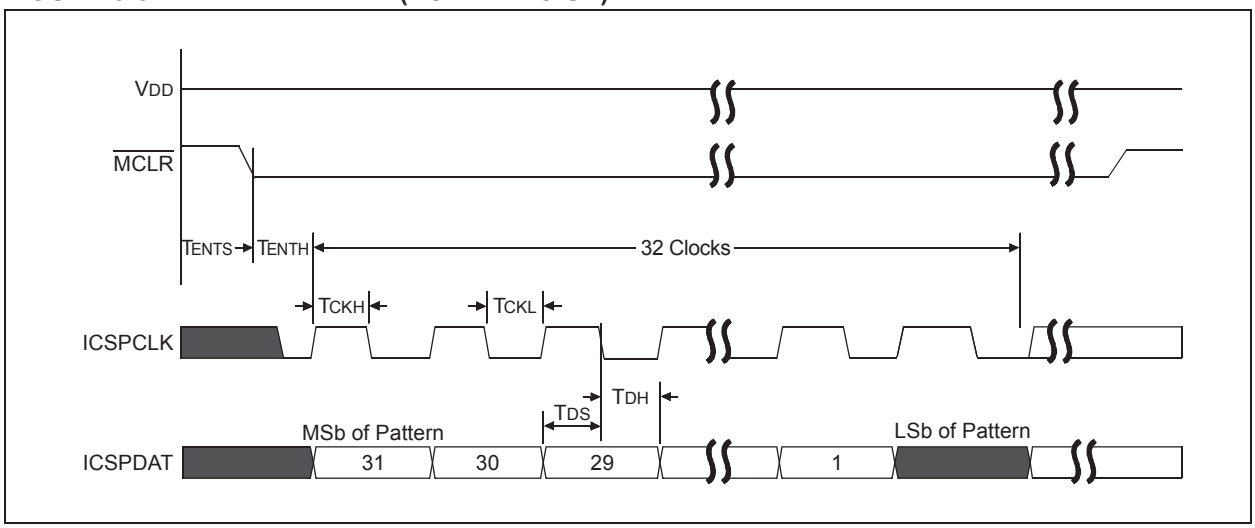
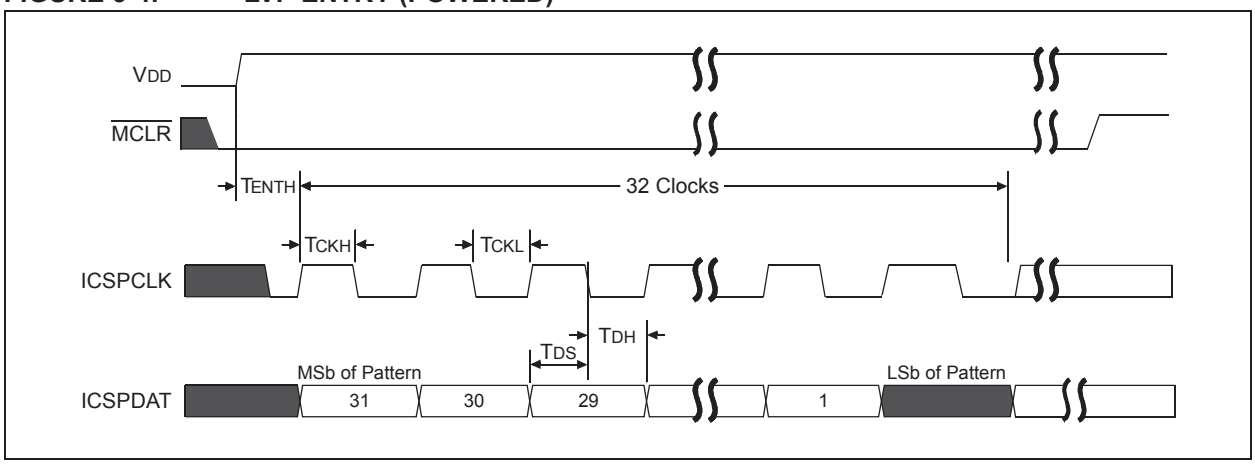


FIGURE 3-4: LVP ENTRY (POWERED)



Exiting Program/Verify mode is done by raising $\overline{\text{MCLR}}$ from below VIL to VIH level (or higher, up to VDD).

Note: To enter LVP mode, the MSb of the most significant nibble must be shifted in first. This differs from entering the key sequence on some other device families.

3.1.3 PROGRAM/VERIFY COMMANDS

Once a device has entered ICSP Program/Verify mode (using either high-voltage or LVP entry), the programming host device may issue nine commands to the microcontroller, each eight bits in length. The commands are summarized in Table 3-1. The commands are used to erase or program the device based on the location of the Program Counter (PC).

Some of the 8-bit commands also have a data payload associated with it (such as Load Data for NVM and Read Data from NVM).

If the programming host device issues an 8-bit command byte that has a data payload associated with it, the host device is responsible for sending an additional 24 clock pulses (for example, three 8-bit bytes) in order to send or receive the payload data associated with the command.

The payload field size is used so as to be compatible with many 8-bit SPI-based systems. Within each 24-bit payload field, the first bit transmitted is always a Start bit, followed by a variable number of Pad bits, followed by the useful data payload bits and ending with one Stop bit. The useful data payload bits are always transmitted Most Significant bit (MSb) first.

When the programming device issues a command that involves a host to microcontroller payload (for example, Load PC Address), the Start, Stop and Pad bits should all be driven by the programmer to '0'. When the programming host device issues a command that involves microcontroller to host payload data (for example, Read Data from NVM), the Start, Stop and Pad bits should be treated as "don't care" bits and the values should be ignored by the host.

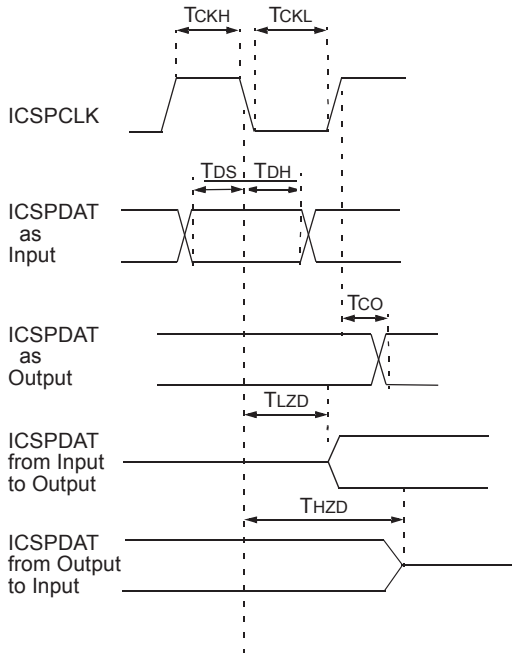
When the programming host device issues an 8-bit command byte to the microcontroller, the host should wait a minimum amount of delay (which is command-specific) prior to sending any additional clock pulses (associated with either a 24-bit data payload field or the next command byte).

TABLE 3-1: ICSP™ COMMAND SET SUMMARY

Command Name	Command Value		Payload Expected	Delay after Command	Data/Note
	Binary (MSb … LSb)	Hex			
Load PC Address	1000 0000	80	Yes	TDLY	Payload value = PC
Bulk Erase Program Memory	0001 1000	18	No	TERAB	Depending on the current value of the PC, one or more memory regions.
Row Erase Program Memory	1111 0000	F0	No	TERAR	The row addressed by the MSbs of the PC is erased; LSbs are ignored.
Load Data for NVM	0000 00J0	00/02	Yes	TDLY	Data is loaded to the data latch addressed by the PC; J = 0: PC is unchanged J = 1: PC = PC + 2 after writing
Read Data from NVM	1111 11J0	FC/FE	Yes	TDLY	Data output '0' if code-protect is enabled; J = 0: PC is unchanged J = 1: PC = PC + 2 after reading
Increment Address	1111 1000	F8	No	TDLY	PC = PC + 2
Begin Internally Timed Programming	1110 0000	E0	No	TPINT	Commits latched data to NVM (self-timed).
Begin Externally Timed Programming	1100 0000	C0	No	TPEXT	Commits latched data to NVM (externally timed). After TPEXT, "End Externally Timed Programming" command must be issued.
End Externally Timed Programming	1000 0010	82	No	TDIS	Should be issued within required time delay (TPEXT) after "Begin Externally Timed Programming" command.

Note: All clock pulses for both the 8-bit commands and the 24-bit payload fields are generated by the host programming device. The microcontroller does not drive the ICSPCLK line. The ICSPDAT signal is a bidirectional data line. For all commands and payload fields, except the Read Data from NVM payload, the host programming device continuously drives the ICSPDAT line. Both the host programmer device and the microcontroller should latch received ICSPDAT values on the falling edge of the ICSPCLK line. When the microcontroller receives ICSPDAT line values from the host programmer, the ICSPDAT values must be valid a minimum of TDS before the falling edges of ICSPCLK and should remain valid for a minimum of TDH after the falling edge of ICSPDAT. See Figure 3-5.

FIGURE 3-5: CLOCK AND DATA TIMING



3.1.3.1 Load Data for NVM

The Load Data for NVM command is used to load one programming data latch (for example, one 16-bit instruction word for program memory/configuration memory/User ID memory or one 8-bit data for a Data EEPROM Memory address). The latched data is written into program or EEPROM memory after the Begin Internally Timed Programming or Begin Externally Timed Programming command is issued (see **Section 3.2 "Programming Algorithms"**). The Load Data for the NVM command can be used to load data for Program Flash Memory (PFM) (see Figure 3-6) or the Data EEPROM Memory (see Figure 3-7). Depending on the value of bit 1 of the command, the PC may or may not be incremented (see Table 3-1).

FIGURE 3-6: LOAD DATA FOR NVM (PFM)

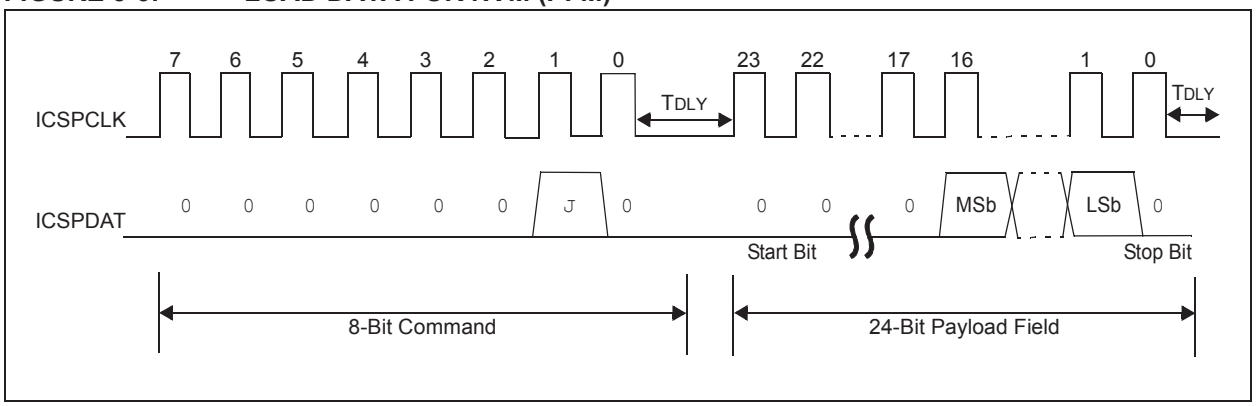
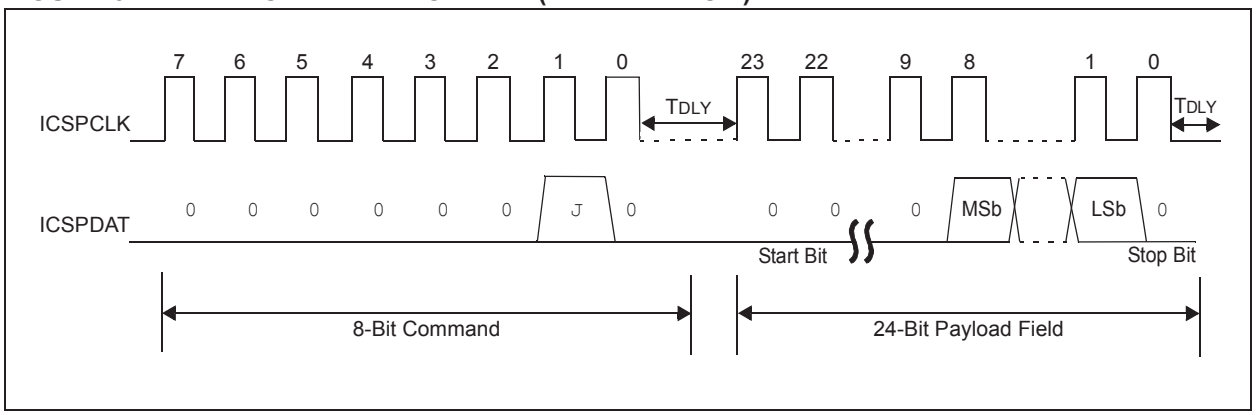


FIGURE 3-7: LOAD DATA FOR NVM (DATA EEPROM)



3.1.3.2 Read Data from NVM

The Read Data from NVM command will transmit data bits out of the current PC address. The ICSPDAT pin will go into Output mode on the first falling edge of the ICSP data payload clock and it will revert to Input mode (high-impedance) after the 24th falling edge of the ICSP data payload clock. The Start and Stop bits are only one-half-of-a-bit-time wide; therefore, they should be ignored by the host programmer device, since the latched value may be indeterminate. Additionally, the host programmer device should only consider the MSb to LSb payload bits as valid and should ignore the values of the Pad bits. If the program memory is code-protected ($\overline{CP}$), the data will be read as zeros (see Figure 3-8 and Figure 3-9). Depending on the value of bit<1> of the command, the PC may or may not be incremented (see Table 3-1). The Read Data for NVM command can be used to read data for Program Flash Memory (PFM) (see Figure 3-8) or the Data EEPROM Memory (see Figure 3-9).

FIGURE 3-8: READ DATA FROM NVM (PFM OR CONFIGURATION WORDS)

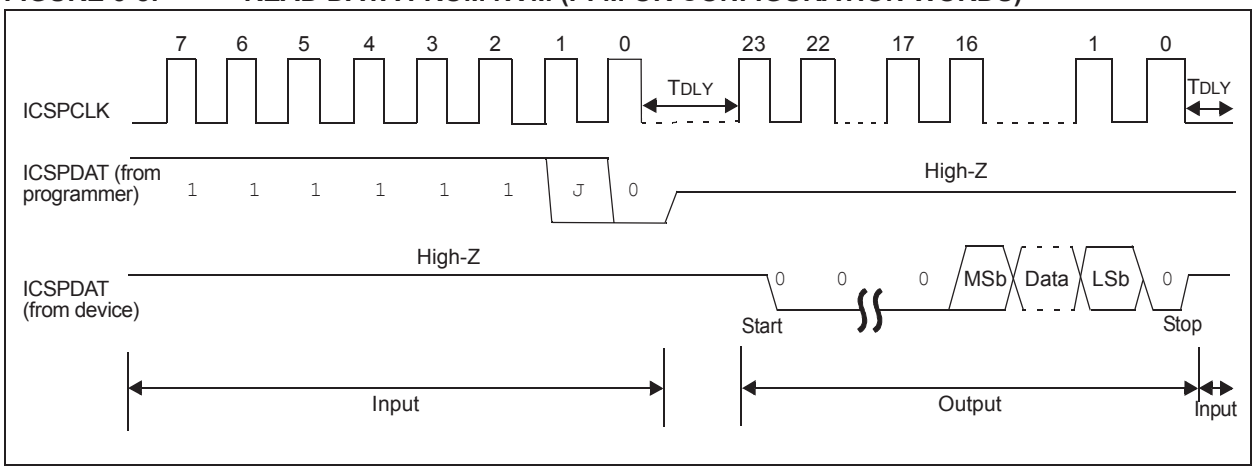
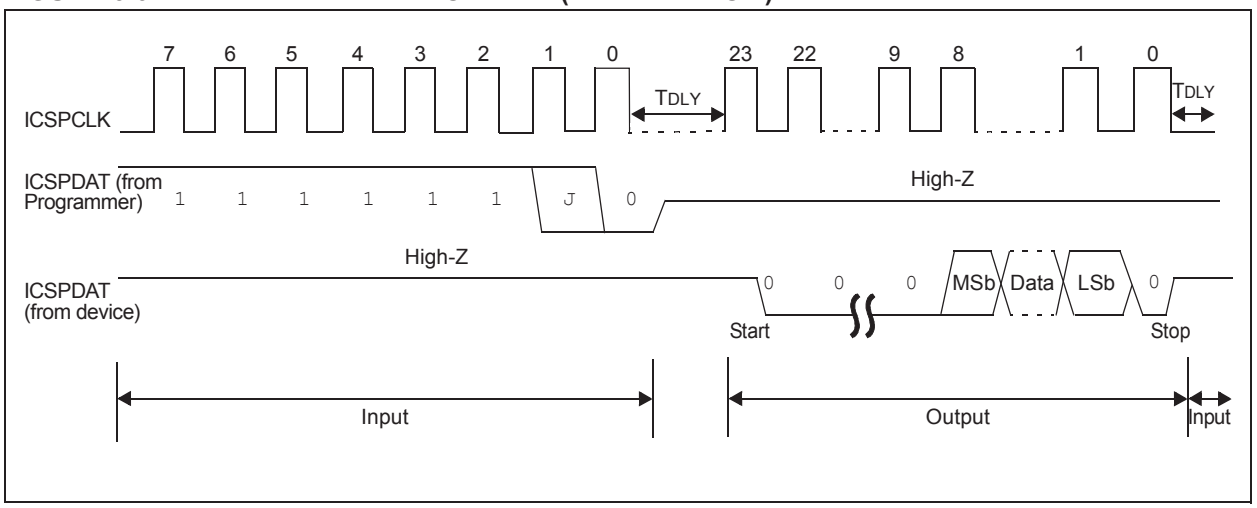


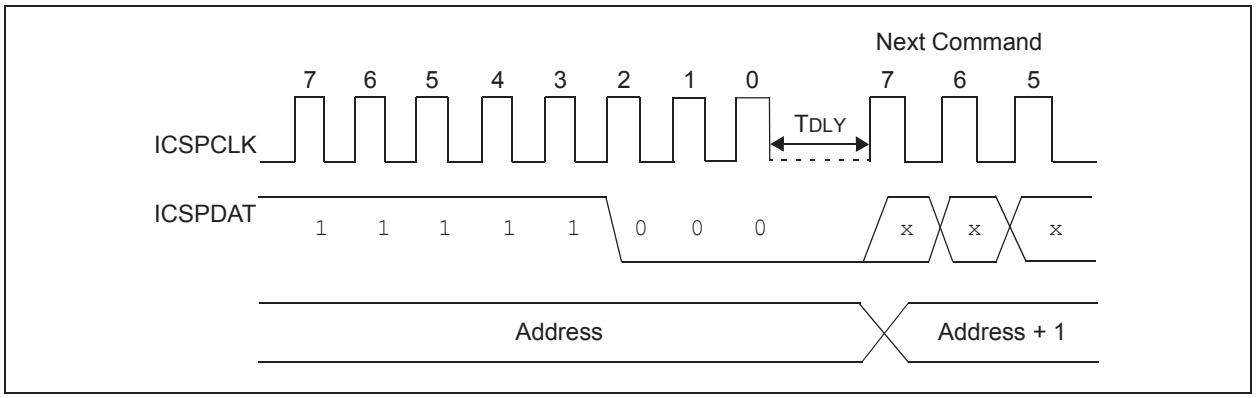
FIGURE 3-9: READ DATA FROM NVM (DATA EEPROM)



3.1.3.3 Increment Address

The address is incremented when this command is received. Depending on the current value of the Program Counter, the increment varies. If the PC points to PFM, then the PC is incremented by 2; if the PC points to data EEPROM, then it is incremented by 1. It is not possible to decrement the address. To reset this counter, the user must use the Load PC Address command.

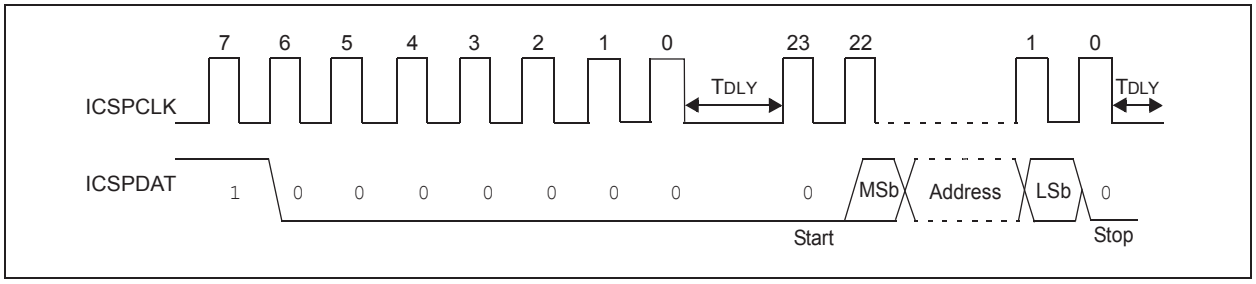
FIGURE 3-10: INCREMENT ADDRESS



3.1.3.4 Load PC Address

The PC value is set using the supplied data. The address implies the memory panel (PFM or Data EEPROM Memory) to be accessed (see Figure 3-11).

FIGURE 3-11: LOAD PC ADDRESS

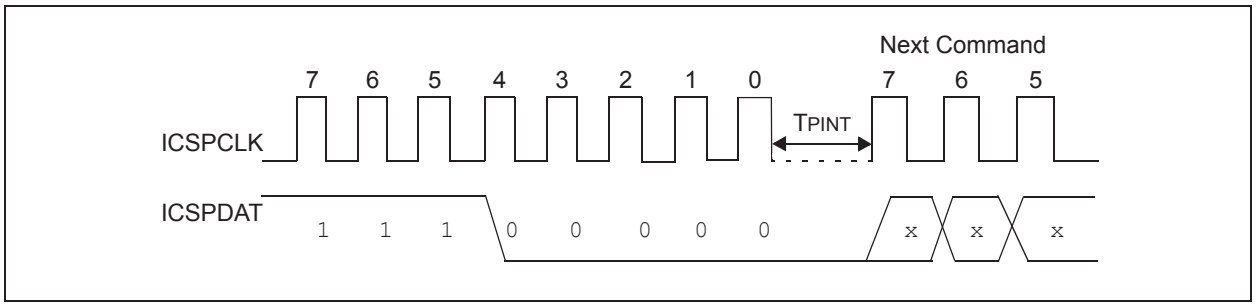


3.1.3.5 Begin Internally Timed Programming

The write programming latches must already have been loaded using the Write Data for NVM command, prior to issuing the Begin Programming command (see **Section 3.2 "Programming Algorithms"**). Programming of the addressed memory will begin after this command is received. An internal timing mechanism executes the write. The user must allow for the erase/write cycle time, TPINT, in order for the programming to complete, prior to issuing the next command byte (see Figure 3-12).

After the programming cycle is complete, all of the data latches are reset to '1'. The command is ignored when the fuse latched values of CP == 0 or CPD == 0 (i.e., if either device memory is currently protected).

FIGURE 3-12: BEGIN INTERNALLY TIMED PROGRAMMING

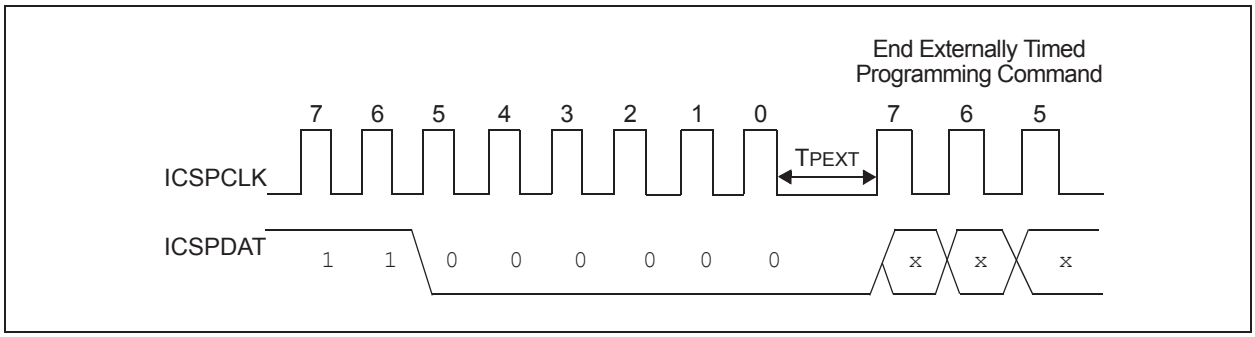


3.1.3.6 Begin Externally Timed Programming

Data to be programmed must be previously loaded by the Load Data for NVM command before every Begin Programming command. To complete the programming, the End Externally Timed Programming command must be sent in the specified time window defined by TPEXT (see Figure 3-13).

Externally timed writes are not supported for Configuration and Calibration bits. Any externally timed write to the Configuration or Calibration Word will have no effect on the targeted word.

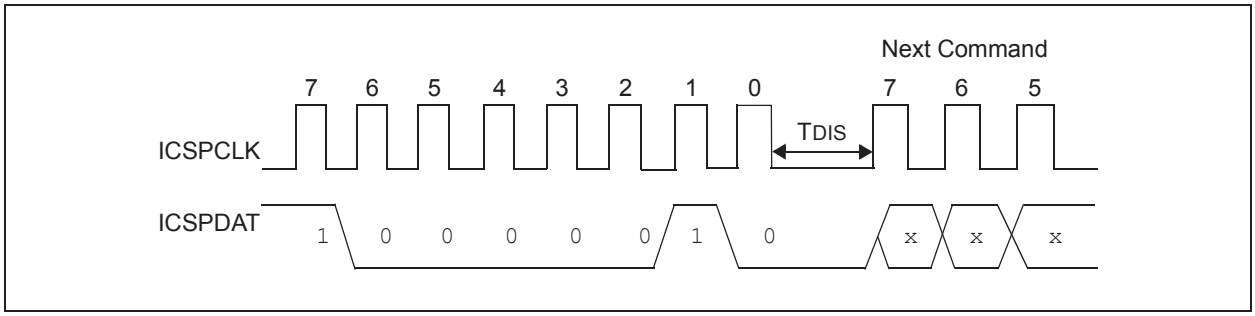
FIGURE 3-13: BEGIN EXTERNALLY TIMED PROGRAMMING



3.1.3.7 End Externally Timed Programming

This command is required to terminate the programming sequence after a Begin Externally Timed Programming command is given. If no programming command is in progress, or if the programming cycle is internally timed, this command will execute as a No Operation (NOP) (see Figure 3-14).

FIGURE 3-14: END EXTERNALLY TIMED PROGRAMMING



3.1.3.8 Bulk Erase Memory

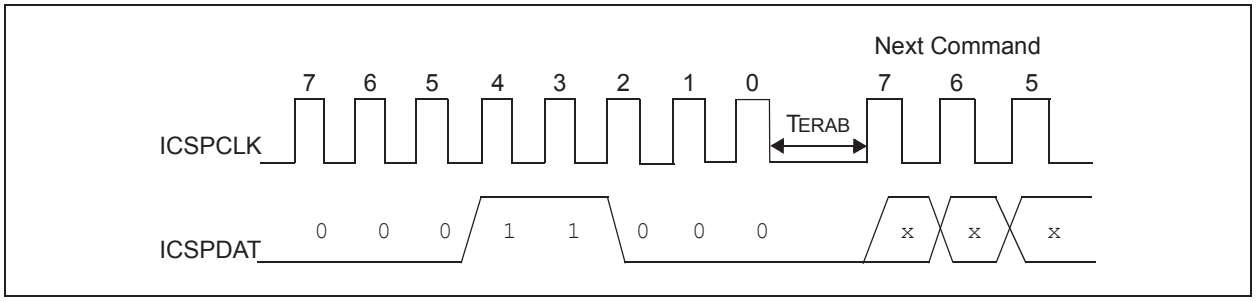
The Bulk Erase command affects specific portions of the memory depending on the initial value of the Program Counter. Whenever a Bulk Erase command is executed, the device will erase all bytes within the regions listed in Table 3-2.

TABLE 3-2: BULK ERASE

Address	Area(s) Erased	
	$\overline{CP}$ = x and $\overline{CPD}$ = 1 (both disabled)	$\overline{CP}$ = x or $\overline{CPD}$ = 0 (either enabled)
00 0000h-01 FFFFh	Program Flash Memory Configuration Words	Program Flash Memory Data EEPROM Configuration Words
30 0000h-30 001Fh	Program Flash Memory User ID Words Configuration Words	Program Flash Memory Data EEPROM User ID Words Configuration Words
31 0000h-3F FFFFh	Data EEPROM Only	Data EEPROM Only

After receiving the Bulk Erase Memory command, the erase will not complete until the time interval, TERAB, has expired (see Figure 3-15). The programming host device should not issue another 8-bit command until after the TERAB interval has fully elapsed.

FIGURE 3-15: BULK ERASE MEMORY



3.1.3.9 Row Erase Memory

The Row Erase Memory command will erase an individual row based on the current address of the Program Counter.

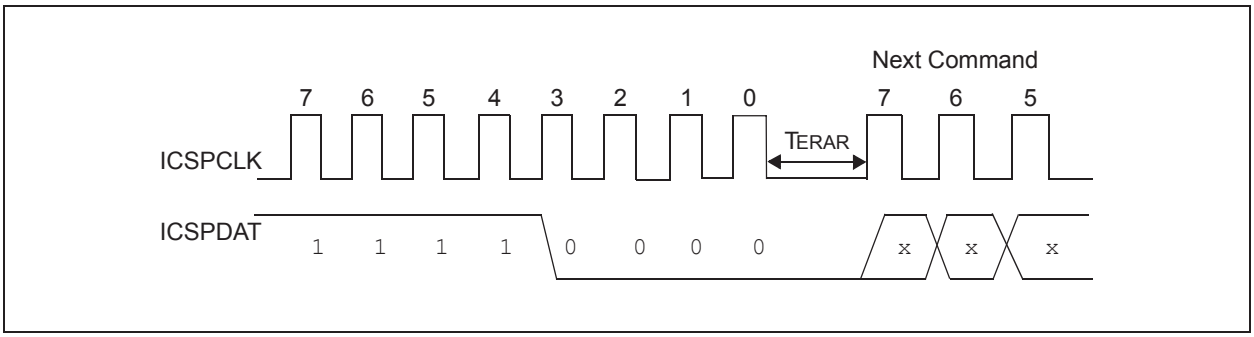
Write and erase operations are done on a row basis. Refer to Table 3-3 for row size of erase and write operations for other devices in the PIC18(L)F2X/4XK40 family. For example, in the PIC18(L)F47K40 device, the row size (number of 16-bit words) for write/erase operation is 32, and the write latches per row (number of 8-bit latches) required for the write/erase operation is 64. If the program memory is code-protected, the Row Erase Program Memory command will be ignored.

The Flash memory row defined by the current PC will be erased. The user must wait TERAR for erasing to complete (see Figure 3-16).

TABLE 3-3: PROGRAM MEMORY ROW SIZES

Variant	Row Size (words)	Byte-Wide Write Latches per Row
PIC18(L)F24K40	32	64
PIC18(L)F25K40		
PIC18(L)F45K40		
PIC18(L)F26K40	32	64
PIC18(L)F46K40		
PIC18(L)F27K40	64	128
PIC18(L)F47K40		

FIGURE 3-16: ROW ERASE MEMORY



3.2 Programming Algorithms

The devices use internal latches to temporarily store the 16-bit words used for programming. The data latches allow the user to write the program words with a single Begin Internally Timed Programming or Begin Externally Timed Programming command. The Load Data for NVM command is used to load a single data latch. The data latch will hold the data until the Begin Internally Timed Programming or Begin Externally Timed Programming command is given.

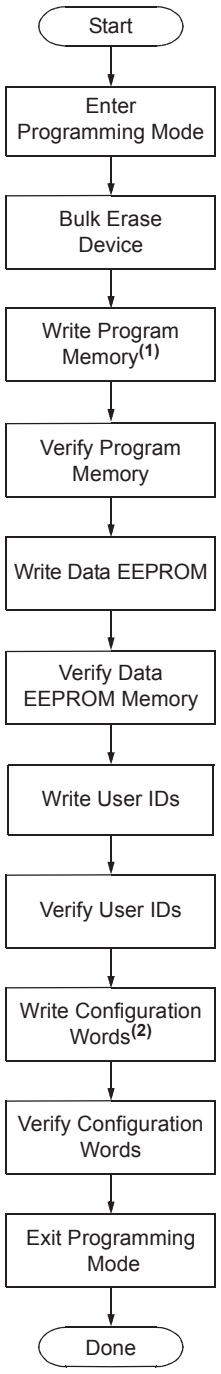
The data latches are aligned with the LSbs of the address. The address used at the time the Begin Internally Timed Programming or Begin Externally Timed Programming command is given will determine which memory row is written. Writes cannot cross a physical row boundary. For example, attempting to write from address, 0002h-0021h, in a 32-latch device will result in data being written to 0020h-003Fh.

If more than the maximum number of latches is written without a Begin Internally Timed Programming or Begin Externally Timed Programming command, the data in the data latches will be overwritten. Figure 3-17 through Figure 3-22 show the recommended flowcharts for programming.

Note: The Program Flash Memory regions are programmed one row at a time (Figure 3-18), while the User ID and Configuration Words are programmed one word at a time (Figure 3-19). The EEPROM memory is programmed one byte at a time. Refer to Table 3-3 for row size.

The value of the PC at the time of issuing the Begin Internally Timed Programming command determines what row (of Program Flash Memory or EEPROM) or what word (of User ID or Configuration Word) will get programmed.

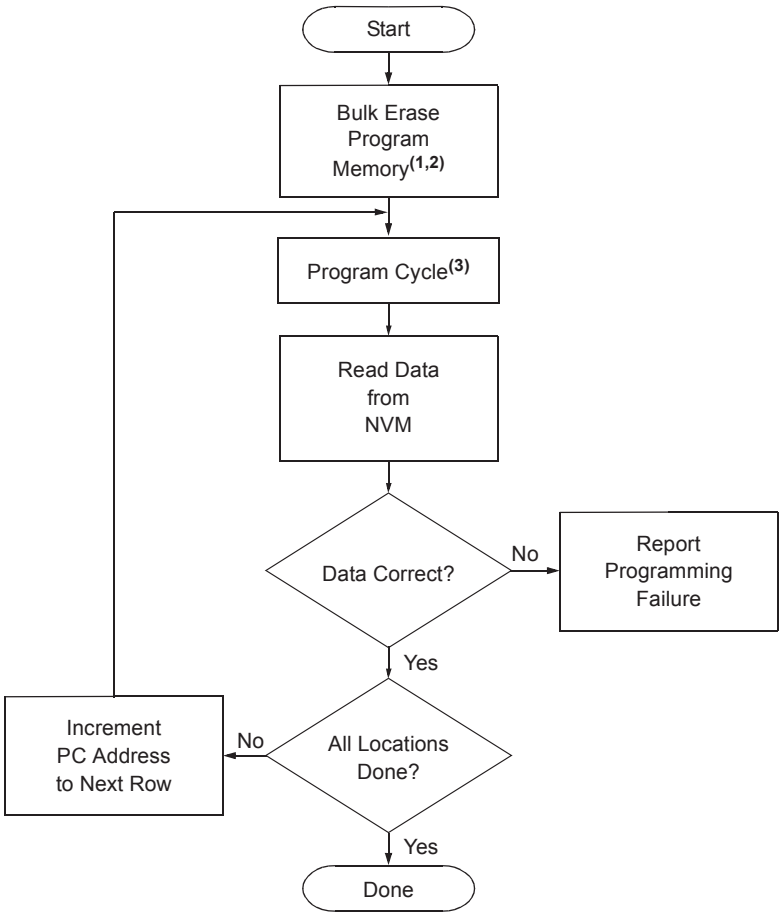
FIGURE 3-17: DEVICE PROGRAM/VERIFY FLOWCHART



Note 1: See Figure 3-18.

2: See Figure 3-21.

FIGURE 3-18: PROGRAM MEMORY FLOWCHART



Note 1: This step is optional if the device has already been erased or has not been previously programmed.
2: If the device is code-protected or must be completely erased, then Bulk Erase the device per Figure 3-22.
3: See Figure 3-19 or Figure 3-20.

FIGURE 3-19: ONE-WORD PROGRAM CYCLE

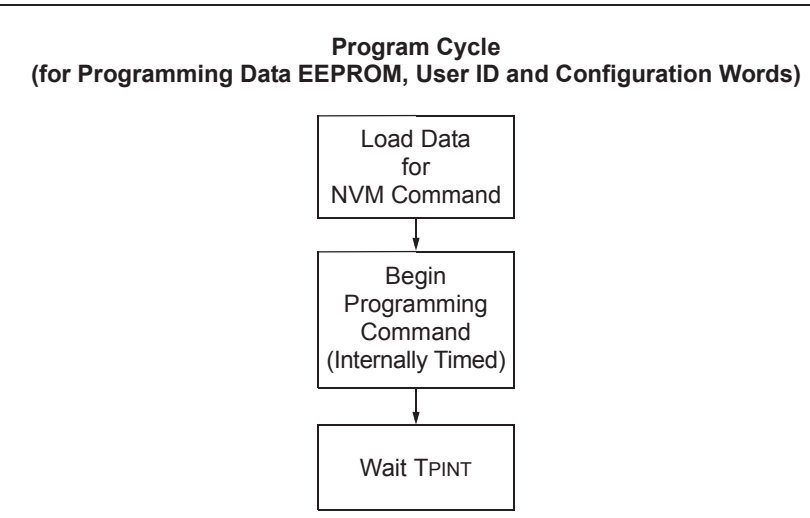
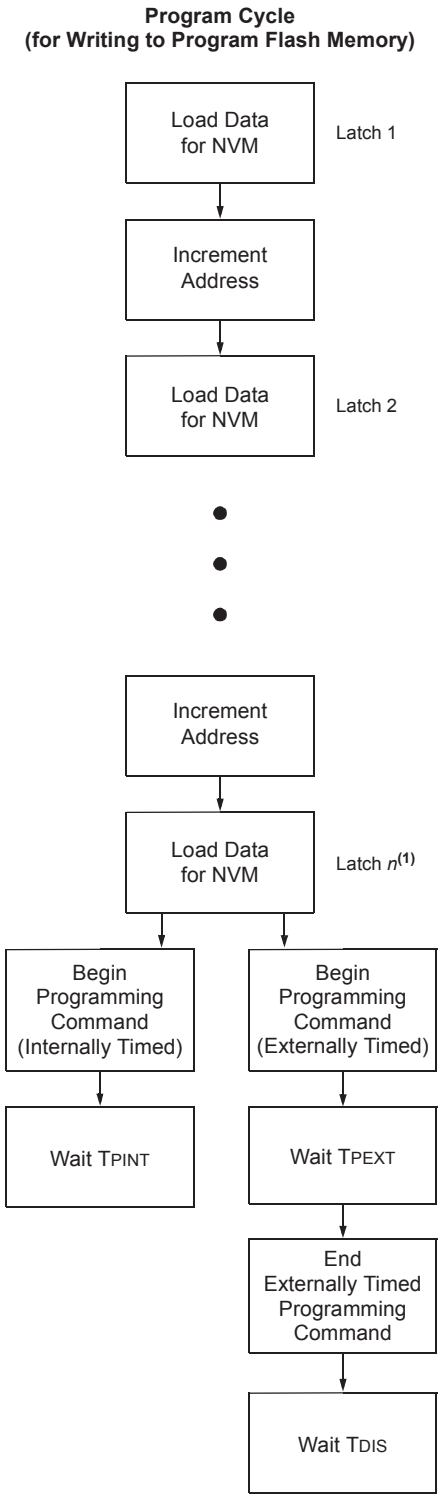
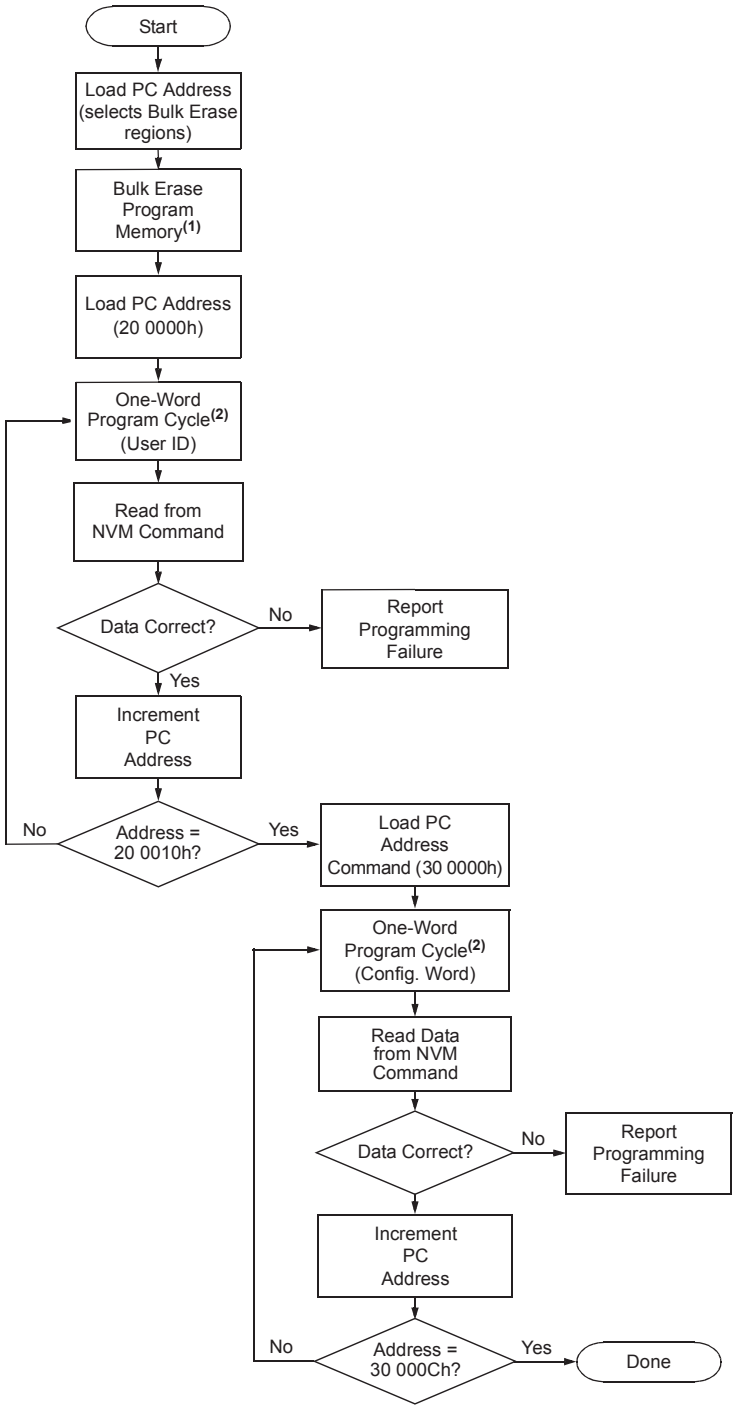


FIGURE 3-20: MULTIPLE WORD PROGRAM CYCLE



Note 1: Refer to Table 3-3 for latch size.

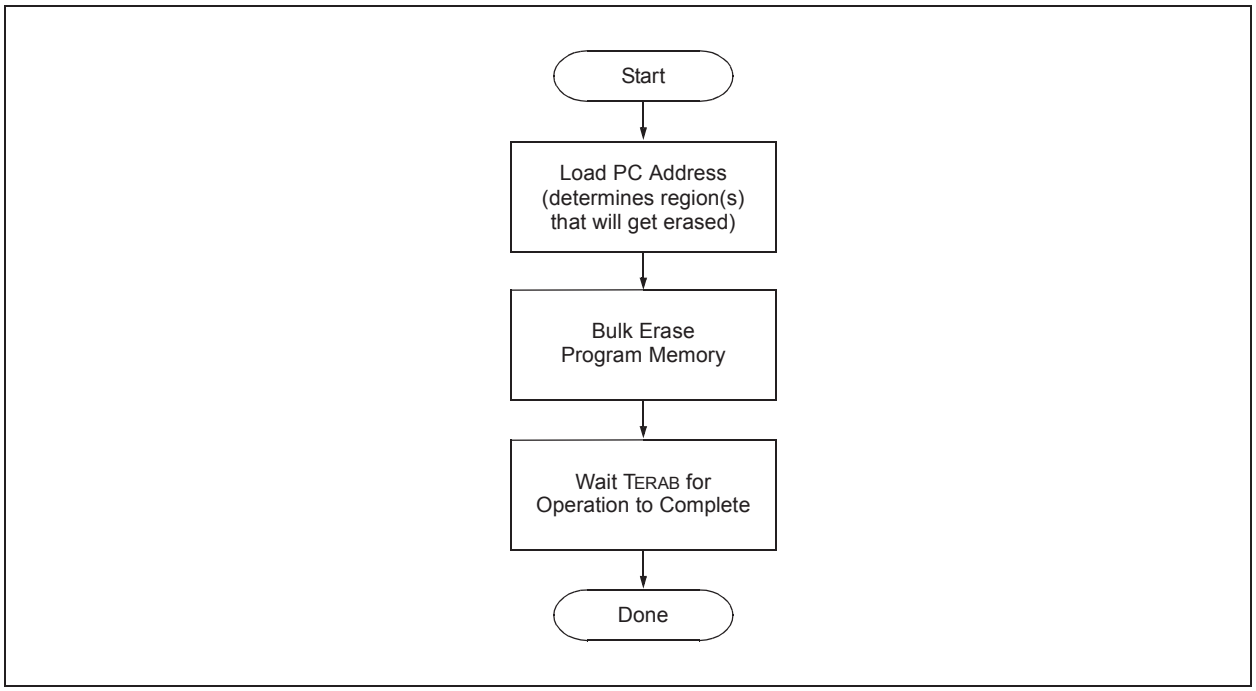
FIGURE 3-21: USER ID AND CONFIGURATION MEMORY PROGRAM FLOWCHART



Note 1: This step is optional if the device is erased or not previously programmed.

2: See Figure 3-19.

FIGURE 3-22: BULK ERASE FLOWCHART



3.3 Code Protection

Code protection is controlled using the $\overline{CP}$ bit. When code protection is enabled, all program memory locations read as '0'. Further programming is disabled for the program memory until the next Bulk Erase operation is performed. Program memory can still be programmed and read during program execution.

The User ID locations and Configuration Words can be programmed and read out regardless of the code protection settings.

3.3.1 PROGRAM MEMORY

Code protection is enabled by programming the $\overline{CP}$ bit to '0'. The only way to disable code protection is to use the Bulk Erase Memory command (with the PC set to an address so as to Bulk Erase all program Flash contents).

3.3.2 DATA EEPROM MEMORY

Data EEPROM Memory protection is enabled by programming the $\overline{CPD}$ bit to '0'. The only way to disable code protection is to use the Bulk Erase Memory command.

3.4 Hex File Usage

3.4.1 EMBEDDING CONFIGURATION WORD INFORMATION IN THE HEX FILE

To allow portability of code, a programmer is required to read the Configuration Word locations from the Hex file. If Configuration Word information is not present in the Hex file, then a simple warning message should be issued. Similarly, while saving a Hex file, all Configuration Word information must be included. An option to not include the Configuration Word information may be provided. When embedding Configuration Word information in the Hex file, it should start at address, 300000h.

Microchip Technology Inc. feels strongly that this feature is important for the benefit of the end customer.

3.4.2 EMBEDDING DATA EEPROM INFORMATION IN THE HEX FILE

To allow portability of code, a programmer is required to read the data EEPROM information from the Hex file. If data EEPROM information is not present, a simple warning message should be issued. Similarly, when saving a Hex file, all data EEPROM information must be included. An option to not include the data EEPROM information may be provided. When embedding data EEPROM information in the Hex file, it should start at address, F00000h.

Microchip Technology Inc. believes that this feature is important for the benefit of the end customer.

3.5 Checksum Computation

The checksum is calculated by two different methods, dependent on the setting of the $\overline{CP}$ Configuration bit. Refer to **Appendix B** for checksum computation examples.

3.5.1 PROGRAM CODE PROTECTION DISABLED

With the program code protection disabled, the checksum is computed by reading the contents of the program memory locations and adding up the program memory data, starting at address, 00 0000h, up to the maximum user-addressable location (e.g., 01 FFFFh for the PIC18F47K40 device). Any Carry bits exceeding 16 bits are ignored. Additionally, the relevant bits of the Configuration Words are added to the checksum. All unimplemented Configuration bits are masked to '0'.

3.5.2 PROGRAM CODE PROTECTION ENABLED

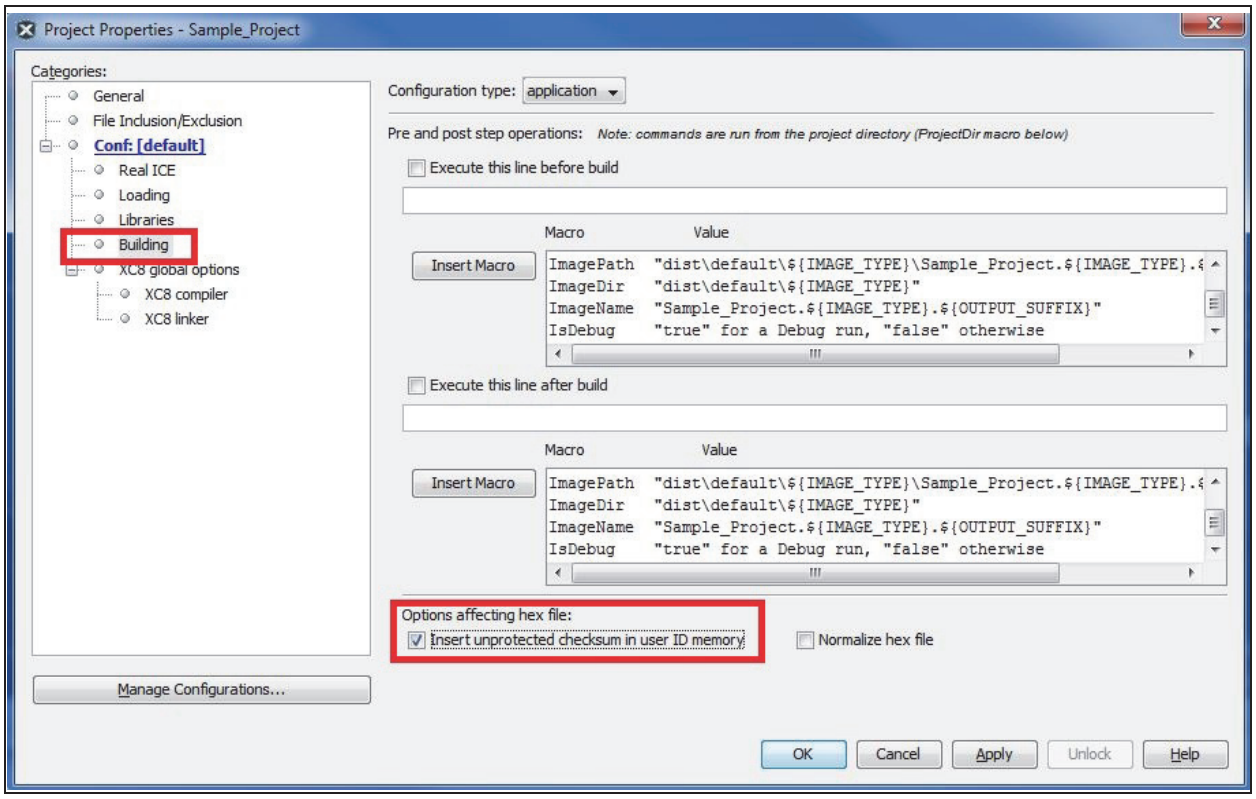
The MPLAB® X IDE can compute the 16-bit checksum of the equivalent unprotected device and store it in the USER ID space. This option can be found in the project properties as shown in Figure 3-23. The unprotected checksum is distributed one nibble per ID location. Each nibble is right justified. The unused USER ID locations are filled with 0x00 and are used to calculate the checksum.

The checksum of a code-protected device is computed in the following manner:

- All of the User ID locations are added to create the sum ID
- The sum ID is then added to the Configuration bits
- All unimplemented Configuration bits are masked to '0'

Note:	The checksum calculation differs depending on the code-protect setting. Since the code memory locations read out differently, depending on the code-protect setting, the examples in **Appendix B** describe how to manipulate the actual code memory values to simulate the values that would be read from a protected device. When calculating a checksum by reading a device, the entire code memory can simply be read and summed. The Configuration Word and ID locations can always be read.

FIGURE 3-23: MPLAB® X IDE CHECKSUM CALCULATION



3.6 Electrical Specifications

Refer to the device-specific data sheet for absolute maximum ratings.

TABLE 3-4: AC/DC CHARACTERISTICS TIMING REQUIREMENTS FOR PROGRAM/VERIFY MODE

AC/DC CHARACTERISTICS			Standard Operating Conditions Production tested at +25°C				
Sym.	**Characteristics**		**Min.**	**Typ.**	**Max.**	**Units**	**Conditions/Comments**
Programming Supply Voltages and Currents							
V_{DD}	Supply Voltage (V_{DDMIN}, V_{DDMAX})	PICXXLFXXKXX	1.80	—	3.60	V	**Note 1**
		PICXXFXXKXX	2.30	—	5.50	V	
V_{PEW}	Read/Write and Row Erase Operations		V_{DDMIN}	—	V_{DDMAX}	V	
V_{BE}	Bulk Erase Operations		V_{BORMAX}	—	V_{DDMAX}	V	**Note 2**
I_{DDI}	Current on V_{DD}, Idle		—	—	1.0	mA	
I_{DDP}	Current on V_{DD}, Programming		—	—	5.0	mA	
	V_{PP}						
I_{PP}	Current on $\overline{MCLR}/V_{PP}$		—	—	600	μA	
V_{IHH}	High Voltage on $\overline{MCLR}/V_{PP}$ for Program/Verify Mode Entry		7.9	—	9.0	V	
T_{VHHR}	$\overline{MCLR}$ Rise Time (V_{IL} to V_{IHH}) for Program/Verify Mode Entry		—	—	1.0	μs	
	I/O Pins						
V_{IH}	(ICSPCLK, ICSPDAT, $\overline{MCLR}/V_{PP}$) Input High Level		0.8 V_{DD}	—	V_{DD}	V	
V_{IL}	(ICSPCLK, ICSPDAT, $\overline{MCLR}/V_{PP}$) Input Low Level		V_{SS}	—	0.2 V_{DD}	V	
V_{OH}	ICSPDAT Output High Level		V_{DD} – 0.7	—	—	V	I_{OH} = 6 mA, V_{DD} = 3.0V
V_{OL}	ICSPDAT Output Low Level		—	—	V_{SS} + 0.6	V	I_{OL} = 10 mA, V_{DD} = 3.0V
Programming Mode Entry and Exit							
T_{ENTS}	Programing Mode Entry Setup Time: ICSPCLK, ICSPDAT Setup Time before V_{DD} or $\overline{MCLR}$↑		100	—	—	ns	
T_{ENTH}	Programing Mode Entry Hold Time: ICSPCLK, ICSPDAT Hold Time after V_{DD} or $\overline{MCLR}$↑		250	—	—	μs	
Serial Program/Verify							
T_{CKL}	Clock Low Pulse Width		100	—	—	ns	
T_{CKH}	Clock High Pulse Width		100	—	—	ns	
T_{DS}	Data in Setup Time before Clock↓		100	—	—	ns	
T_{DH}	Data in Hold Time after Clock↓		100	—	—	ns	
T_{CO}	Clock↑ to Data Out Valid (during a Read Data command)		0	—	80	ns	

Note 1: Bulk Erased devices default to Brown-out Reset enabled with BORV = 1 (low trip point). V_{DDMIN} is the V_{BOR} threshold (with BORV = 1) when performing Low-Voltage Programming on a Bulk Erased device to ensure that the device is not held in Brown-out Reset.

2: The hardware requires V_{DD} to be above the BOR threshold, at the ~2.4V nominal setting, in order to perform Bulk Erase operations. This threshold does not depend on the BORV Configuration bit settings. The threshold is the same for both F and LF devices, even though the LF devices may not have a user-configurable ~2.4V nominal BOR trip point setting. Refer to the microcontroller device data sheet specifications for min./typ./max. limits of the V_{BOR} level (at the BORV = 0 setting of F devices).

3: Externally timed writes are not supported for Configuration and Calibration bits.

TABLE 3-4: AC/DC CHARACTERISTICS TIMING REQUIREMENTS FOR PROGRAM/VERIFY MODE (CONTINUED)

AC/DC CHARACTERISTICS		Standard Operating Conditions Production tested at +25°C				
Sym.	**Characteristics**	**Min.**	**Typ.**	**Max.**	**Units**	**Conditions/Comments**
TLZD	Clock↓ to Data Low-Impedance (during a Read Data command)	0	—	80	ns	
THZD	Clock↓ to Data High-Impedance (during a Read Data command)	0	—	80	ns	
TDLY	Data Input not Driven to Next Clock Input (delay required between command/data or command/ command)	1.0	—	—	μs	
TERAB	Bulk Erase Cycle Time	—	—	25.2	ms	
TERAR	Row Erase Cycle Time	—	—	2.8	ms	
TPINT	Internally Timed Programming Operation Time	—	—	2.8	ms	Program memory
		—	—	5.6	ms	Configuration Words/ Data EEPROM Memory
TPEXT	Delay Required between Begin Externally Timed Programming and End Externally Timed Programming Commands	1.0	—	2.1	ms	**Note 3**
TDIS	Delay Required after End Externally Timed Programming Command	300	—	—	μs	
TEXIT	Time Delay when Exiting Program/Verify Mode	1	—	—	μs	

Note 1: Bulk Erased devices default to Brown-out Reset enabled with BORV = 1 (low trip point). VDDMIN is the VBOR threshold (with BORV = 1) when performing Low-Voltage Programming on a Bulk Erased device to ensure that the device is not held in Brown-out Reset.

2: The hardware requires VDD to be above the BOR threshold, at the ~2.4V nominal setting, in order to perform Bulk Erase operations. This threshold does not depend on the BORV Configuration bit settings. The threshold is the same for both F and LF devices, even though the LF devices may not have a user-configurable ~2.4V nominal BOR trip point setting. Refer to the microcontroller device data sheet specifications for min./typ./max. limits of the VBOR level (at the BORV = 0 setting of F devices).

3: Externally timed writes are not supported for Configuration and Calibration bits.

APPENDIX A: REVISION HISTORY

Revision A (11/2014)

Initial release of the document.

Revision B (09/2015)

Updated Table 3-2, Table B-1 and Table B-2; updated Example B-1 through Example B-4; updated Register B-1 and Register B-6. Minor updates to text and formatting were incorporated throughout the document.

Revision C (02/2017)

Updated section 3.5.2 Program Code protection Enabled. Added Figure 3-23. Updated Table B-2, Example B-2, Example B-4. Updated Register B-1, Register B-4. Minor updates to text and formatting were incorporated throughout the document.

APPENDIX B: PIC18(L)F2X/4XK40 DEVICE ID, CHECKSUMS AND PINOUT DESCRIPTIONS

TABLE B-1: CONFIGURATION WORD AND MASK

Device	Device ID	Config. 1L		Config. 1H		Config. 2L		Config. 2H		Config. 3L		Config. 3H		Config. 4L		Config. 4H		Config. 5L			Config. 5H			Config. 6L		Config. 6H	
		Word (Hex)	Mask (Hex)	Word (Hex)	Mask (Hex)	Word (Hex)	Mask (Hex)	Word (Hex)	Mask (Hex)	Word (Hex)	Mask (Hex)	Word (Hex)	Mask (Hex)	Word (Hex)	Mask (Hex)	Word (Hex)	Mask (Hex)	Unprotected	Code-Protected	Mask (Hex)	Unprotected	Code-Protected	Mask (Hex)	Word	Mask (Hex)	Word	Mask (Hex)
PIC18F47K40	6900h	FF	77	FF	29	FF	E3	FF	BF	FF	7F	FF	3F	FF	FF	FF	37	FF	FE	03	FF	FF	00	FF	FF	FF	02
PIC18F46K40	6920h	FF	77	FF	29	FF	E3	FF	BF	FF	7F	FF	3F	FF	0F	FF	37	FF	FE	03	FF	FF	00	FF	0F	FF	02
PIC18F45K40	6940h	FF	77	FF	29	FF	E3	FF	BF	FF	7F	FF	3F	FF	0F	FF	37	FF	FE	03	FF	FF	00	FF	0F	FF	02
PIC18F27K40	6960h	FF	77	FF	29	FF	E3	FF	BF	FF	7F	FF	3F	FF	FF	FF	37	FF	FE	03	FF	FF	00	FF	FF	FF	02
PIC18F26K40	6980h	FF	77	FF	29	FF	E3	FF	BF	FF	7F	FF	3F	FF	0F	FF	37	FF	FE	03	FF	FF	00	FF	0F	FF	02
PIC18F25K40	69A0h	FF	77	FF	29	FF	E3	FF	BF	FF	7F	FF	3F	FF	0F	FF	37	FF	FE	03	FF	FF	00	FF	0F	FF	02
PIC18F24K40	69C0h	FF	77	FF	29	FF	E3	FF	BF	FF	7F	FF	3F	FF	03	FF	37	FF	FE	03	FF	FF	00	FF	03	FF	02
PIC18LF47K40	69E0h	FF	77	FF	29	FF	E3	FF	BF	FF	7F	FF	3F	FF	FF	FF	37	FF	FE	03	FF	FF	00	FF	FF	FF	02
PIC18LF46K40	6A00h	FF	77	FF	29	FF	E3	FF	BF	FF	7F	FF	3F	FF	0F	FF	37	FF	FE	03	FF	FF	00	FF	0F	FF	02
PIC18LF45K40	6A20h	FF	77	FF	29	FF	E3	FF	BF	FF	7F	FF	3F	FF	0F	FF	37	FF	FE	03	FF	FF	00	FF	0F	FF	02
PIC18LF27K40	6A40h	FF	77	FF	29	FF	E3	FF	BF	FF	7F	FF	3F	FF	FF	FF	37	FF	FE	03	FF	FF	00	FF	FF	FF	02
PIC18LF26K40	6A60h	FF	77	FF	29	FF	E3	FF	BF	FF	7F	FF	3F	FF	0F	FF	37	FF	FE	03	FF	FF	00	FF	0F	FF	02
PIC18LF25K40	6A80h	FF	77	FF	29	FF	E3	FF	BF	FF	7F	FF	3F	FF	0F	FF	37	FF	FE	03	FF	FF	00	FF	0F	FF	02
PIC18LF24K40	6AA0h	FF	77	FF	29	FF	E3	FF	BF	FF	7F	FF	3F	FF	03	FF	37	FF	FE	03	FF	FF	00	FF	03	FF	02

TABLE B-2: CHECKSUM VALUES

Device	Checksum			
	Unprotected		Code-Protected	
	Blank	AAh at First and Last Address	Blank	AAh at First and Last Address
PIC18F47K40	053A	0490	054B	0546
PIC18F46K40	035A	02B0	036B	0366
PIC18F45K40	835A	82B0	0373	036E
PIC18F27K40	053A	0490	054B	0546
PIC18F26K40	035A	02B0	036B	0366
PIC18F25K40	835A	82B0	0373	036E
PIC18F24K40	C342	C298	0356	0360
PIC18LF47K40	053A	0490	054B	0546
PIC18LF46K40	035A	02B0	036B	0366
PIC18LF45K40	835A	82B0	0373	036E
PIC18LF27K40	053A	0490	054B	0546
PIC18LF26K40	035A	02B0	036B	0366
PIC18LF25K40	835A	82B0	0373	036E
PIC18LF24K40	C342	C298	0356	0360

EXAMPLE B-1: CHECKSUM COMPUTED WITH PROGRAM CODE PROTECTION DISABLED: PIC18(L)F24K40, BLANK DEVICE

PIC18(L)F24K40	Sum of Memory Addresses from 0000h to 3FFFh	C000h (4000h * 00FFh)
	Configuration Word 1L	FFh
	Configuration Word 1L Mask	77h
	Configuration Word 1H	FFh
	Configuration Word 1H Mask	29h
	Configuration Word 2L	FFh
	Configuration Word 2L Mask	E3h
	Configuration Word 2H	FFh
	Configuration Word 2H Mask	BFh
	Configuration Word 3L	FFh
	Configuration Word 3L Mask	7Fh
	Configuration Word 3H	FFh
	Configuration Word 3H Mask	3Fh
	Configuration Word 4L	03h
	Configuration Word 4L Mask	FFh
	Configuration Word 4H	FFh
	Configuration Word 4H Mask	37h
	Configuration Word 5L Unprotected	FFh
	Configuration Word 5L Mask	03h
	Configuration Word 5H Unprotected	FFh
	Configuration Word 5H Mask	00h
	Configuration Word 6L	FFh
	Configuration Word 6L Mask	03h
	Configuration Word 6H	FFh
	Configuration Word 6H Mask	02h

Checksum = C000h + (FFh AND 77h) + (FFh AND 29h) + (FFh AND E3h) + (FFh AND BFh)
+ (FFh AND 7Fh) + (FFh AND 3Fh) + (FFh AND 03h) + (FFh AND 37h)
+ (FFh AND 03h) + (FFh AND 00h) + (FFh AND 03h) + (FFh AND 02h)
= C000h + 77h + 29h + E3h + BFh + 7Fh + 3Fh + 03h + 37h + 03h + 00h + 03h + 02h
= C342h

EXAMPLE B-2: CHECKSUM COMPUTED WITH PROGRAM CODE PROTECTION DISABLED: PIC18(L)F24K40, AAh AT FIRST AND LAST ADDRESS

PIC18(L)F24K40	Sum of Memory Addresses from 0000h to 3FFFh	BF56h (AAh + (3FFEh * 00FFh) + AAh)
	Configuration Word 1L	FFh
	Configuration Word 1L Mask	77h
	Configuration Word 1H	FFh
	Configuration Word 1H Mask	29h
	Configuration Word 2L	FFh
	Configuration Word 2L Mask	E3h
	Configuration Word 2H	FFh
	Configuration Word 2H Mask	BFh
	Configuration Word 3L	FFh
	Configuration Word 3L Mask	7Fh
	Configuration Word 3H	FFh
	Configuration Word 3H Mask	3Fh
	Configuration Word 4L	FFh
	Configuration Word 4L Mask	03h
	Configuration Word 4H	FFh
	Configuration Word 4H Mask	37h
	Configuration Word 5L Unprotected	FFh
	Configuration Word 5L Mask	03h
	Configuration Word 5H Unprotected	FFh
	Configuration Word 5H Mask	00h
	Configuration Word 6L	FFh
	Configuration Word 6L Mask	03h
	Configuration Word 6H	FFh
	Configuration Word 6H Mask	02h

Checksum = BF56h + (FFh AND 77h) + (FFh AND 29h) + (FFh AND E3h) + (FFh AND BFh)
+ (FFh AND 7Fh) + (FFh AND 3Fh) + (FFh AND 03h) + (FFh AND 37h)
+ (FFh AND 03h) + (FFh AND 00h) + (FFh AND 03h) + (FFh AND 02h)
= BF56h + 77h + 29h + E3h + BFh + 7Fh + 3Fh + 03h + 37h + 03h + 00h + 03h + 02h
= C298h

EXAMPLE B-3: CHECKSUM COMPUTED WITH PROGRAM CODE PROTECTION ENABLED: PIC18(L)F24K40, BLANK DEVICE

PIC18(L)F24K40	Configuration Word 1L	FFh
	Configuration Word 1L Mask	77h
	Configuration Word 1H	FFh
	Configuration Word 1H Mask	29h
	Configuration Word 2L	FFh
	Configuration Word 2L Mask	E3h
	Configuration Word 2H	FFh
	Configuration Word 2H Mask	BFh
	Configuration Word 3L	FFh
	Configuration Word 3L Mask	7Fh
	Configuration Word 3H	FFh
	Configuration Word 3H Mask	3Fh
	Configuration Word 4L	FFh
	Configuration Word 4L Mask	03h
	Configuration Word 4H	FFh
	Configuration Word 4H Mask	37h
	Configuration Word 5L Protected	FEh
	Configuration Word 5L Mask	03h
	Configuration Word 5H Protected	FFh
	Configuration Word 5H Mask	00h
	Configuration Word 6L	FFh
	Configuration Word 6L Mask	03h
	Configuration Word 6H	FFh
	Configuration Word 6H Mask	02h

Checksum = (FFh AND 77h) + (FFh AND 29h) + (FFh AND E3h) + (FFh AND BFh)
+ (FFh AND 7Fh) + (FFh AND 3Fh) + (FFh AND 03h) + (FFh AND 37h)
+ (FEh AND 03h) + (FFh AND 00h) + (FFh AND 03h) + (FFh AND 02h) + SUM_ID
= 77h + 29h + E3h + BFh + 7Fh + 3Fh + 03h + 37h + 02h + 00h + 03h + 02h + 0015h
= 0356h

SUM_ID = Bytewise sum of lower four bits of all User ID locations

SUM_ID = 000Ch + 0003h + 0004h + 0002h + 0000h + 0000h + 0000h + 0000h = 0015h

EXAMPLE B-4: CHECKSUM COMPUTED WITH PROGRAM CODE PROTECTION ENABLED: PIC18(L)F24K40, AAh AT FIRST AND LAST ADDRESS

PIC18(L)F24K40	Configuration Word 1L	FFh
	Configuration Word 1L Mask	77h
	Configuration Word 1H	FFh
	Configuration Word 1H Mask	29h
	Configuration Word 2L	FFh
	Configuration Word 2L Mask	E3h
	Configuration Word 2H	FFh
	Configuration Word 2H Mask	BFh
	Configuration Word 3L	FFh
	Configuration Word 3L Mask	7Fh
	Configuration Word 3H	FFh
	Configuration Word 3H Mask	3Fh
	Configuration Word 4L	FFh
	Configuration Word 4L Mask	03h
	Configuration Word 4H	FFh
	Configuration Word 4H Mask	37h
	Configuration Word 5L Protected	FEh
	Configuration Word 5L Mask	03h
	Configuration Word 5H Protected	FFh
	Configuration Word 5H Mask	00h
	Configuration Word 6L Protected	FFh
	Configuration Word 6L Mask	03h
	Configuration Word 6H Protected	FFh
	Configuration Word 6H Mask	02h

Checksum = (FFh AND 77h) + (FFh AND 29h) + (FFh AND E3h) + (FFh AND BFh)
+ (FFh AND 7Fh) + (FFh AND 3Fh) + (FFh AND 03h) + (FFh AND 37h)
+ (FEh AND 03h) + (FFh AND 00h) + (FFh AND 03h) + (FFh AND 02h) + SUM_ID
= 77h + 29h + E3h + BFh + 7Fh + 3Fh + 03h + 37h + 02h + 00h + 03h + 02h + 001Fh
= 0360h

SUM_ID = Bytewise sum of lower four bits of all User ID locations

SUM_ID = 000Ch + 0002h + 0009h + 0008h + 0000h + 0000h + 0000h + 0000h = 001Fh

TABLE B-3: PROGRAMMING PIN LOCATIONS BY PACKAGE TYPE

Device	Package	Package Code	Package Drawing Number(1)	VDD	VSS	MCLR		ICSPCLK		ICSPDAT	
				PIN	PIN	PIN	PORT	PIN	PORT	PIN	PORT
PIC18(L)F24K40 PIC18(L)F25K40	28-Pin SPDIP	(SP)	C04-070	20	19,8	1	RE3	27	RB6	28	RB7
	28-Pin SOIC	(SO)	C04-052	20	19,8	1	RE3	27	RB6	28	RB7
	28-Pin SSOP	(SS)	C04-073	20	19,8	1	RE3	27	RB6	28	RB7
	28-Pin QFN	(ML)	C04-105	17	16,5	26	RE3	24	RB6	25	RB7
PIC18(L)F45K40	28-Pin UQFN	(MV)	C04-152	17	16,5	26	RE3	24	RB6	25	RB7
	40-Pin PDIP	(P)	C04-016	32,11	31,12	1	RE3	39	RB6	40	RB7
	40-Pin UQFN	(MV)	C04-156	26,7	27,6	16	RE3	14	RB6	15	RB7
	44-Pin TQFP	(PT)	C04-076	28,7	29,6	18	RE3	16	RB6	17	RB7
	44-Pin QFN	(ML)	C04-103	28,8,7	31,30,6	18	RE3	16	RB6	17	RB7
	28-Pin SPDIP	(SP)	C04-070	20	19,8	1	RE3	27	RB6	28	RB7
PIC18(L)F26K40	28-Pin SOIC	(SO)	C04-052	20	19,8	1	RE3	27	RB6	28	RB7
	28-Pin SSOP	(SS)	C04-073	20	19,8	1	RE3	27	RB6	28	RB7
	28-Pin QFN	(ML)	C04-105	17	16,5	26	RE3	24	RB6	25	RB7
PIC18(L)F46K40	28-Pin UQFN	(MV)	C04-152	17	16,5	26	RE3	24	RB6	25	RB7
	40-Pin PDIP	(P)	C04-016	32,11	31,12	1	RE3	39	RB6	40	RB7
	40-Pin UQFN	(MV)	C04-156	26,7	27,6	16	RE3	14	RB6	15	RB7
	44-Pin TQFP	(PT)	C04-076	28,7	29,6	18	RE3	16	RB6	17	RB7
	44-Pin QFN	(ML)	C04-103	28,8,7	31,30,6	18	RE3	16	RB6	17	RB7
PIC18(L)F27K40	28-Pin SPDIP	(SP)	C04-070	20	19,8	1	RE3	27	RB6	28	RB7
	28-Pin SOIC	(SO)	C04-052	20	19,8	1	RE3	27	RB6	28	RB7
	28-Pin SSOP	(SS)	C04-073	20	19,8	1	RE3	27	RB6	28	RB7
	28-Pin QFN	(ML)	C04-105	17	16,5	26	RE3	24	RB6	25	RB7
PIC18(L)F47K40	40-Pin PDIP	(P)	C04-016	32,11	31,12	1	RE3	39	RB6	40	RB7
	40-Pin UQFN	(MV)	C04-156	26,7	27,6	16	RE3	14	RB6	15	RB7
	44-Pin TQFP	(PT)	C04-076	28,7	29,6	18	RE3	16	RB6	17	RB7
	44-Pin QFN	(ML)	C04-103	28,8,7	31,30,6	18	RE3	16	RB6	17	RB7

Note 1: The most current package drawings can be found in the Microchip Packaging Specification, DS00000049, found at http://www.microchip.com/packaging. The drawing numbers listed above do not include the current revision designator which is added at the end of the number.

TABLE B-4: SUMMARY OF CONFIGURATION WORDS

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Default/ Unprogrammed Value
30 0000h	CONFIG 1L	—	RSTOSC2	RSTOSC1	RSTOSC0	—	FEXTOSC2	FEXTOSC1	FEXTOSC0	1111 1111
30 0001h	CONFIG 1H	—	—	FCMEN	—	CSWEN	—	—	$\overline{\text{CLKOUTEN}}$	1111 1111
30 0002h	CONFIG 2L	BOREN1	BOREN0	$\overline{\text{LPBOREN}}$	—	—	—	$\overline{\text{PWRTE}}$	MCLRE	1111 1111
30 0003h	CONFIG 2H	$\overline{\text{XINST}}$	—	$\overline{\text{DEBUG}}$	STVREN	PPS1WAY	ZCDDIS	BORV1	BORV0	1111 1111
30 0004h	CONFIG 3L	—	WDTE1	WDTE0	WDTCPS4	WDTCPS3	WDTCPS2	WDTCPS1	WDTCPS0	1111 1111
30 0005h	CONFIG 3H	—	—	WDTCCS2	WDTCCS1	WDTCCS0	WDTCWS2	WDTCWS1	WDTCWS0	1111 1111
30 0006h	CONFIG 4L	WRT7	WRT6	WRT5	WRT4	WRT3	WRT2	WRT1	WRT0	1111 1111
30 0007h	CONFIG 4H	—	—	LVP	SCANE	—	WRTD	WRTB	WRTC	1111 1111
30 0008h	CONFIG 5L	—	—	—	—	—	—	$\overline{\text{CPD}}$	$\overline{\text{CP}}$	1111 1111
30 000Ah	CONFIG 6L	EBTR7	EBTR6	EBTR5	EBTR4	EBTR3	EBTR2	EBTR1	EBTR0	1111 1111
30 000Bh	CONFIG 6H	—	—	—	—	—	—	EBTRB	—	1111 1111

REGISTER B-1: CONFIGURATION WORD 1L (30 0000h) – OSCILLATORS

U-1	R/W-1	R/W-1	R/W-1	U-1	R/W-1	R/W-1	R/W-1
—	RSTOSC2	RSTOSC1	RSTOSC0	—	FEXTOSC2	FEXTOSC1	FEXTOSC0
bit 7							bit 0

Legend:			
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '1'	
-n = Value for blank device	'1' = Bit is set	'0' = Bit is cleared	x = Bit is unknown

bit 7 **Unimplemented:** Read as '1'

bit 6-4 **RSTOSC<2:0>:** Power-up Default Value for COSC bits

This value is the Reset default value for COSC and selects the oscillator first used by user software. Refer to COSC operation.

111 = EXTOSC operating per FEXTOSC<2:0> bits (device manufacturing default)
110 = HFINTOSC with HFFRQ = 4 MHz and CDIV = 4:1
101 = LFINTOSC
100 = SOSC
011 = Reserved
010 = EXTOSC with 4x PLL, with EXTOSC operating per FEXTOSC<2:0> bits
001 = Reserved
000 = HFINTOSC with HFFRQ = 64 MHz and CDIV = 1:1; resets COSC/NOSC to 3'b110

bit 3 **Unimplemented:** Read as '1'

bit 2-0 **FEXTOSC<2:0>:** FEXTOSC External Oscillator Mode Selection bits

111 = EC (External Clock) above 8 MHz; PFM set to high power (device manufacturing default)
110 = EC (External Clock) for 500 kHz to 8 MHz; PFM set to medium power
101 = EC (External Clock) below 500 kHz; PFM set to low power
100 = Oscillator is not enabled
011 = Reserved (do not use)
010 = HS (crystal oscillator) above 8 MHz; PFM set to high power
001 = XT (crystal oscillator) above 500 kHz, below 8 MHz; PFM set to medium power
000 = LP (crystal oscillator) optimized for 32.768 kHz; PFM set to low power

REGISTER B-2: CONFIGURATION WORD 1H (30 0001h) – OSCILLATORS

U-1	U-1	R/W-1	U-1	R/W-1	U-1	U-1	R/W-1
—	—	FCMEN	—	CSWEN	—	—	$\overline{\text{CLKOUTEN}}$
bit 7							bit 0

Legend:			
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '1'	
-n = Value for blank device	'1' = Bit is set	'0' = Bit is cleared	x = Bit is unknown

bit 7-6 **Unimplemented:** Read as '1'

bit 5 **FCMEN:** Fail-Safe Clock Monitor Enable bit
1 = FSCM timer is enabled
0 = FSCM timer is disabled

bit 4 **Unimplemented:** Read as '1'

bit 3 **CSWEN:** Clock Switch Enable bit
1 = Writing to NOSC and NDIV is allowed
0 = The NOSC and NDIV bits cannot be changed by user software

bit 2-1 **Unimplemented:** Read as '1'

bit 0 **$\overline{\text{CLKOUTEN}}$:** Clock Out Enable bit
If FEXTOSC<2:0> = EC (high, mid or low) or Not Enabled:
1 = CLKOUT function is disabled; I/O or oscillator function on OSC2
0 = CLKOUT function is enabled; FOSC/4 clock appears at OSC2
Otherwise:
This bit is ignored.

REGISTER B-3: CONFIGURATION WORD 2L (30 0002h) – SUPERVISOR

R/W-1	R/W-1	R/W-1	U-1	U-1	U-1	R/W-1	R/W-1
BOREN1	BOREN0	$\overline{\text{LPBOREN}}$	—	—	—	$\overline{\text{PWRTE}}$	MCLRE
bit 7							bit 0

Legend:			
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '1'	
-n = Value for blank device	'1' = Bit is set	'0' = Bit is cleared	x = Bit is unknown

bit 7-6 **BOREN<1:0>:** Brown-out Reset Enable bits
When enabled, Brown-out Reset Voltage (V_{BOR}) is set by the BORV bit.
11 = Brown-out Reset is enabled, SBOREN bit is ignored
10 = Brown-out Reset is enabled while running, disabled in Sleep; SBOREN is ignored
01 = Brown-out Reset is enabled according to SBOREN
00 = Brown-out Reset is disabled

bit 5 **$\overline{\text{LPBOREN}}$:** Low-Power BOR Enable bit
1 = ULPBOR is disabled
0 = ULPBOR is enabled

bit 4-2 **Unimplemented:** Read as '1'

bit 1 **$\overline{\text{PWRTE}}$:** Power-up Timer Enable bit
1 = PWRT is disabled
0 = PWRT is enabled

bit 0 **MCLRE:** Master Clear ($\overline{\text{MCLR}}$) Enable bit
If LVP = 1:
RE3 pin function is $\overline{\text{MCLR}}$.
If LVP = 0:
1 = $\overline{\text{MCLR}}$ pin is $\overline{\text{MCLR}}$
0 = $\overline{\text{MCLR}}$ pin function is a port defined function

REGISTER B-4: CONFIGURATION WORD 2H (30 0003h) – SUPERVISOR

R/W-1	U-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1
$\overline{\text{XINST}}$	—	$\overline{\text{DEBUG}}$	STVREN	PPS1WAY	$\overline{\text{ZCD}}$	BORV1(1)	BORV0(1)
bit 7							bit 0

Legend:			
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '1'	
-n = Value for blank device	'1' = Bit is set	'0' = Bit is cleared	x = Bit is unknown

bit 7 **$\overline{\text{XINST}}$:** Extended Instruction Set Enable bit
1 = Extended instruction set and Indexed Addressing mode are disabled (Legacy mode)
0 = Extended instruction set and Indexed Addressing mode are enabled

bit 6 **Unimplemented:** Read as '1'

bit 5 **$\overline{\text{DEBUG}}$:** Debugger Enable bit
1 = Background debugger is disabled
0 = Background debugger is enabled

bit 4 **STVREN:** Stack Overflow/Underflow Reset Enable bit
1 = Stack overflow or underflow will cause a Reset
0 = Stack overflow or underflow will not cause a Reset

bit 3 **PPS1WAY:** PPSLOCK One-Way Set Enable bit
1 = The PPSLOCKED bit can only be set once after an unlocking sequence is executed; once PPSLOCK is set, all future changes to PPS registers are prevented
0 = The PPSLOCKED bit can be set and cleared as needed (provided an unlocking sequence is executed)

bit 2 **$\overline{\text{ZCD}}$:** ZCD Disable bit
1 = ZCD is disabled; ZCD can be enabled by setting the ZCDSEN bit of the ZCDCON register
0 = ZCD is always enabled, ZCDMD bit is ignored

bit 1-0 **BORV<1:0>:** Brown-out Reset Voltage Selection bits(1)
PIC18FXXK40 Devices:
11 = Brown-out Reset Voltage (V_{BOR}) is set to 2.45V
10 = Brown-out Reset Voltage (V_{BOR}) is set to 2.45V
01 = Brown-out Reset Voltage (V_{BOR}) is set to 2.7V
00 = Brown-out Reset Voltage (V_{BOR}) is set to 2.85V
PIC18LFXXK40 Device:
11 = Brown-out Reset Voltage (V_{BOR}) is set to 1.90V
10 = Brown-out Reset Voltage (V_{BOR}) is set to 2.45V
01 = Brown-out Reset Voltage (V_{BOR}) is set to 2.7V
00 = Brown-out Reset Voltage (V_{BOR}) is set to 2.85V

Note 1: The higher voltage setting is recommended for operation at or above 16 MHz.

REGISTER B-5: CONFIGURATION WORD 3L (30 0004h) – WINDOWED WATCHDOG TIMER

U-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1
—	WDTE1	WDTE0	WDTCPS4	WDTCPS3	WDTCPS2	WDTCPS1	WDTCPS0
bit 7							bit 0

Legend:			
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '1'	
-n = Value for blank device	'1' = Bit is set	'0' = Bit is cleared	x = Bit is unknown

bit 7 **Unimplemented:** Read as '1'

bit 6-5 **WDTE<1:0>:** WDT Operating Mode bits

00 = WDT is disabled, SWDTEN is ignored
01 = WDT is enabled/disabled by the SWDTEN bit in WDTCON0
10 = WDT is enabled while Sleep = 0, suspended when Sleep = 1; SWDTEN is ignored
11 = WDT is enabled regardless of Sleep; SWDTEN is ignored

bit 4-0 **WDTCPS<4:0>:** WDT Period Select bits

WDTCPS<4:0>	WDTPS at POR				Software Control of WDTPS?
	Value	Divider Ratio		Typical Time-out (FIN = 31 kHz)	
00000	00000	1:32	2^5	1 ms	No
00001	00001	1:64	2^6	2 ms	
00010	00010	1:128	2^7	4 ms	
00011	00011	1:256	2^8	8 ms	
00100	00100	1:512	2^9	16 ms	
00101	00101	1:1024	2^{10}	32 ms	
00110	00110	1:2048	2^{11}	64 ms	
00111	00111	1:4096	2^{12}	128 ms	
01000	01000	1:8192	2^{13}	256 ms	
01001	01001	1:16384	2^{14}	512 ms	
01010	01010	1:32768	2^{15}	1s	
01011	01011	1:65536	2^{16}	2s	
01100	01100	1:131072	2^{17}	4s	
01101	01101	1:262144	2^{18}	8s	
01110	01110	1:524299	2^{19}	16s	
01111	01111	1:1048576	2^{20}	32s	
10000	10000	1:2097152	2^{21}	64s	
10001	10001	1:4194304	2^{22}	128s	
10010	10010	1:8388608	2^{23}	256s	
10011 ... 11110	10011 ... 11110	1:32	2^5	1 ms	No
11111	01011	1:65536	2^{16}	2s	Yes

REGISTER B-6: CONFIGURATION WORD 3H (30 0005h) – WINDOWED WATCHDOG TIMER

U-1	U-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1
—	—	WDTCCS2	WDTCCS1	WDTCCS0	WDTCWS2	WDTCWS1	WDTCWS0
bit 7							bit 0

Legend:			
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '1'	
-n = Value for blank device	'1' = Bit is set	'0' = Bit is cleared	x = Bit is unknown

bit 7-6 **Unimplemented:** Read as '1'

bit 5-3 **WDTCCS<2:0>:** WDT Input Clock Selector bits

If WDTE<1:0> Fuses = 2'b00:
This bit is ignored.

Otherwise:
000 = WDT reference clock is the 31.0 kHz LFINTOSC (default value)
001 = WDT reference clock is the 31.25 kHz HFINTOSC (MFINTOSC)
010 = Reserved (default to LFINTOSC)
•
•
•
110 = Reserved (default to LFINTOSC)
111 = Software control

bit 2-0 **WDTCWS<2:0>:** WDT Window Select bits

WDTCWS	Window at POR			Software Control of Window	Keyed Access Required?
	Value	Window Delay Percent of Time	Window Opening Percent of Time		
000	000	87.5	12.5	No	Yes
001	001	75	25		
010	010	62.5	37.5		
011	011	50	50		
100	100	37.5	62.5		
101	101	25	75		
110	111	n/a	100		
111	111	n/a	100	Yes	No

REGISTER B-7: CONFIGURATION WORD 4L (30 0006h) – MEMORY WRITE PROTECTION

R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1
WRT7(1)	WRT6(1)	WRT5(1)	WRT4(1)	WRT3(1)	WRT2(1)	WRT1(1)	WRT0(1)
bit 7							bit 0

Legend:			
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '1'	
-n = Value for blank device	'1' = Bit is set	'0' = Bit is cleared	x = Bit is unknown

bit 7-0 **WRT*n*:** User NVM Self-Write Protection bits(1)
0 = Memory Block *n* is write-protected
1 = Memory Block *n* is NOT write-protected

Note 1: Refer to Table 2-2 for details on implementation of the individual WRTx bits.

REGISTER B-8: CONFIGURATION WORD 4H (30 0007h) – MEMORY WRITE PROTECTION

U-1	U-1	R/W-1	R/W-1	U-1	R/W-1	R/W-1	R/W-1
—	—	LVP	SCANE	—	WRTD	WRTB	WRTC
bit 7							bit 0

Legend:			
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '1'	
-n = Value for blank device	'1' = Bit is set	'0' = Bit is cleared	x = Bit is unknown

bit 7-6 **Unimplemented:** Read as '1'

bit 5 **LVP:** Low-Voltage Programming Enable bit
0 = HV on $\overline{MCLR}$/VPP must be used for programming
1 = Low-Voltage Programming is enabled; $\overline{MCLR}$/VPP pin function is $\overline{MCLR}$, MCLRE Configuration bit is ignored
The LVP bit cannot be written (to zero) while operating from the LVP programming interface. The purpose of this rule is to prevent the user from dropping out of LVP mode while programming from LVP mode or accidentally eliminating LVP mode from the configuration state.

bit 4 **SCANE:** Scanner Enable bit
1 = Scanner module is available for use, SCANMD bit enables the module
0 = Scanner module is NOT available for use, SCANMD bit is ignored

bit 3 **Unimplemented:** Read as '1'

bit 2 **WRTD:** Data EEPROM Write Protection bit
0 = Data EEPROM is write-protected
1 = Data EEPROM is NOT write-protected

bit 1 **WRTB:** Boot Block Write Protection bit
0 = Boot block is write-protected
1 = Boot block is NOT write-protected

bit 0 **WRTC:** Configuration Register Write Protection bit
0 = Configuration register is write-protected
1 = Configuration register is NOT write-protected

REGISTER B-9: CONFIGURATION WORD 5L (30 0008h) – CODE PROTECTION

U-1	U-1	U-1	U-1	U-1	U-1	R/W-1	R/W-1
—	—	—	—	—	—	$\overline{CPD}$	$\overline{CP}$
bit 7							bit 0

Legend:			
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '1'	
-n = Value for blank device	'1' = Bit is set	'0' = Bit is cleared	x = Bit is unknown

bit 7-2 **Unimplemented:** Read as '1'

bit 1 **$\overline{CPD}$:** Data NVM Memory Code Protection bit
- 1 = Data NVM code protection is disabled
- 0 = Data NVM code protection is enabled

bit 0 **$\overline{CP}$:** User NVM Program Memory Code Protection bit
- 1 = User NVM code protection is disabled
- 0 = User NVM code protection is enabled

REGISTER B-10: CONFIGURATION WORD 6L (30 000Ah) – MEMORY READ PROTECTION

R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1
EBTR7(1)	EBTR6(1)	EBTR5(1)	EBTR4(1)	EBTR3(1)	EBTR2(1)	EBTR1(1)	EBTR0(1)
bit 7							bit 0

Legend:			
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '1'	
-n = Value for blank device	'1' = Bit is set	'0' = Bit is cleared	x = Bit is unknown

bit 7-0 **EBTR*n*:** Table Read Protection bits(1)
- 0 = Memory Block *n* is protected from Table Reads executed in other blocks
- 1 = Memory Block *n* is NOT protected from Table Reads executed in other blocks

Note 1: Refer to Table 2-2 for details on implementation of the individual EBTRx bits.

REGISTER B-11: CONFIGURATION WORD 6H (30 000Bh) – MEMORY READ PROTECTION

U-1	U-1	U-1	U-1	U-1	U-1	R/W-1	U-1
—	—	—	—	—	—	EBTRB	—
bit 7							bit 0

Legend:			
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '1'	
-n = Value for blank device	'1' = Bit is set	'0' = Bit is cleared	x = Bit is unknown

bit 7-2 **Unimplemented:** Read as '1'

bit 1 **EBTRB:** Table Read Protection bit
- 0 = Memory boot block is protected from Table Reads executed in other blocks
- 1 = Memory boot block is NOT protected from Table Reads executed in other blocks

bit 0 **Unimplemented:** Read as '1'

Note the following details of the code protection feature on Microchip devices:

- Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

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Microchip received ISO/TS-16949:2009 certification for its worldwide headquarters, design and wafer fabrication facilities in Chandler and Tempe, Arizona; Gresham, Oregon and design centers in California and India. The Company's quality system processes and procedures are for its PIC® MCUs and dsPIC® DSCs, KEELOQ® code hopping devices, Serial EEPROMs, microperipherals, nonvolatile memory and analog products. In addition, Microchip's quality system for the design and manufacture of development systems is ISO 9001:2000 certified.

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